

- Status Register Feature
- Electronic Identification
  - JEDEC 1-byte manufacturer ID and 2-byte device ID
  - RES command for 1-byte Device ID
  - Both REMS and REMS2 commands for 1-byte manufacturer ID and 1-byte device ID

### **HARDWARE FEATURES**

- SCLK Input
  - Serial clock input
- SI Input
  - Serial Data Input
- SO Output
  - Serial Data Output
- WP#/ACC pin
  - Hardware write protection and program/erase acceleration
- HOLD# pin
  - pause the chip without diselecting the chip
- PACKAGE
  - 16-pin SOP (300mil)
  - 8-land WSON (8x6mm or 6x5mm)
  - 8-pin SOP (200mil, 150mil)
  - 8-pin PDIP (300mil)
  - 8-land USON (4x4mm)
  - All Pb-free devices are RoHS Compliant

### **ALTERNATIVE**

 Security Serial Flash (MX25L1615D/MX25L3215D/MX25L6415D) may provides additional protection features for option. The datasheet is provided under NDA.

### **GENERAL DESCRIPTION**

The MX25L1605D are 16,777,216 bit serial Flash memory, which is configured as  $2,097,152 \times 8$  internally. When it is in two I/O read mode, the structure becomes 8,388,608 bits x 2. The MX25L3205D are 33,554,432 bit serial Flash memory, which is configured as  $4,194,304 \times 8$  internally. When it is in two I/O read mode, the structure becomes 16,772,216 bits x 2. The MX25L6405D are 67,108,864 bit serial Flash memory, which is configured as  $8,388,608 \times 8$  internally. When it is in two I/O read mode, the structure becomes 33,554,432 bits x 2. (please refer to the "Two I/O Read mode" section). The MX25L1605D/3205D/6405D feature a serial peripheral interface and software protocol allowing operation on a simple 3-wire bus. The three bus signals are a clock input (SCLK), a serial data input (SI), and a serial data output (SO). Serial access to the device is enabled by CS# input.

When it is in two I/O read mode, the SI pin and SO pin become SIO0 pin and SIO1 pin for address/dummy bits input and data output.

The MX25L1605D/3205D/6405D provides seguential read operation on whole chip.

After program/erase command is issued, auto program/ erase algorithms which program/ erase and verify the specified page or sector/block locations will be executed. Program command is executed on byte basis, or page (256 bytes) basis, or word basis for Continuously program mode, and erase command is executes on sector (4K-byte), or block (64K-byte), or whole chip basis.

To provide user with ease of interface, a status register is included to indicate the status of the chip. The status read command can be issued to detect completion status of a program or erase operation via WIP bit.

Advanced security features enhance the protection and security functions, please see security features section for more details.

When the device is not in operation and CS# is high, it is put in standby mode and draws less than 20uA DC current.

The MX25L1605D/3205D/6405D utilizes Macronix's proprietary memory cell, which reliably stores memory contents even after typical 100,000 program and erase cycles.

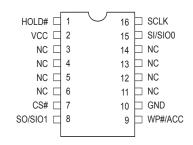
**Table 1. Additional Feature Comparison** 

	Additional Features	Profection and Security 1		Read Performance	Identifier			
Part		Flexible Block	512-bit secured	2 I/O Read	Device ID	Device ID	Device ID	RDID
		Protection	OTP	(50MHz)	(command: AB	(command: 90	(command: EF	(command: 9F
ı	lame	(BP0-BP3)	OIF	(30101112)	hex)	hex)	hex)	hex)
	MX25L1605D	V	V	V	14 (hex)	C2 14 (hex) (if ADD=0)	C2 14 (hex) (if ADD=0)	C2 20 15 (hex)
	MX25L3205D	V	V	V	15 (hex)	C2 15 (hex) (if ADD=0)	C2 15 (hex) (if ADD=0)	C2 20 16 (hex)
	MX25L6405D	V	V	V	16 (hex)	C2 16 (hex) (if ADD=0)	C2 16 (hex) (if ADD=0)	C2 20 17 (hex)

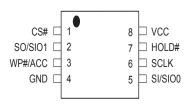


### **PIN CONFIGURATIONS**

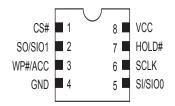
# 16-PIN SOP (300mil)



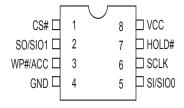
# 8-PIN SOP (200mil, 150mil)



### 8-LAND WSON (8x6mm, 6x5mm), USON (4x4mm)



# 8-PIN PDIP (300mil)



### **PACKAGE OPTIONS**

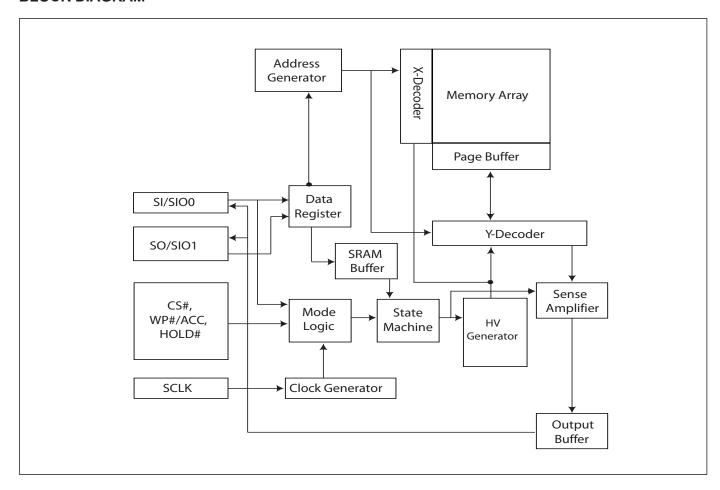
	16M	32M	64M
150mil 8-SOP	V		
200mil 8-SOP	V	V	
300mil 16-SOP	V	V	V
300mil 8-PDIP	V	V	
6x5mm WSON	V	V	
8x6mm WSON			V
4x4mm USON	V	V	

### **PIN DESCRIPTION**

SYMBOL	DESCRIPTION					
CS#	Chip Select					
SI/SIO0	Serial Data Input (for 1 x I/O)/ Serial Data Input & Output (for 2xI/O read mode)					
SO/SIO1	Serial Data Output (for 1 x I/O)/ Serial Data Input & Output (for 2xI/O read mode)					
SCLK	Clock Input					
WP#/ACC	Write protection: connect to GND; 9.5~10.5V for program/erase acceleration: connect to 9.5~10.5V					
HOLD#	Hold, to pause the device without deselecting the device					
VCC	+ 3.3V Power Supply					
GND	Ground					



# **BLOCK DIAGRAM**



### **DATA PROTECTION**

The MX25L1605D/3205D/6405D is designed to offer protection against accidental erasure or programming caused by spurious system level signals that may exist during power transition. During power up the device automatically resets the state machine in the standby mode. In addition, with its control register architecture, alteration of the memory contents only occurs after successful completion of specific command sequences. The device also incorporates several features to prevent inadvertent write cycles resulting from VCC power-up and power-down transition or system noise.

- Valid command length checking: The command length will be checked whether it is at byte base and completed on byte boundary.
- Write Enable (WREN) command: WREN command is required to set the Write Enable Latch bit (WEL) before
  other command to change data. The WEL bit will return to reset stage under following situation:
  - Power-up
  - Write Disable (WRDI) command completion
  - Write Status Register (WRSR) command completion
  - Page Program (PP) command completion
  - Continuously Program mode (CP) instruction completion
  - Sector Erase (SE) command completion
  - Block Erase (BE) command completion
  - Chip Erase (CE) command completion
- Deep Power Down Mode: By entering deep power down mode, the flash device also is under protected from writing all commands except Release from deep power down mode command (RDP) and Read Electronic Signature command (RES).
- Advanced Security Features: there are some protection and securuity features which protect content from inadvertent write and hostile access.

### I. Block lock protection

- The Software Protected Mode (SPM) use (BP3, BP2, BP1, BP0) bits to allow part of memory to be protected as read only. The proected area definition is shown as table of "Protected Area Sizes", the protected areas are more flexible which may protect various area by setting value of BP0-BP3 bits. Please refer to table of "protected area sizes".
- The Hardware Protected Mode (HPM) use WP#/ACC to protect the (BP3, BP2, BP1, BP0) bits and SRWD bit.

MX25L	<sub>-</sub> 1605D
MX25L	.3205D
MX25L	.6405D

**Table 2. Protected Area Sizes** 

	Status bit			Protect Level					
BP3	BP2	BP1	BP0	16Mb	32Mb	64Mb			
0	0	0	0	0 (none)	0 (none)	0 (none)			
0	0	0	1	1 (1block, block 31th)	1 (1block, block 63th)	1 (2block, block 126th-127th)			
0	0	1	0	2 (2blocks, block 30th-31th)	2 (2blocks, block 62th-63th)	2 (4blocks, block 124th-127th)			
0	0	1	1	3 (4blocks, block 28th-31th)	3 (4blocks, block 60th-63th)	3 (8blocks, block 120th-127th)			
0	1	0	0	4 (8blocks, block 24th-31th)	4 (8blocks, block 56th-63th)	4(16blocks, block 112th-127th)			
0	1	0	1	5 (16blocks, block 16th-31th)	5 (16blocks, block 48th-63th)	5 (32blocks, block 96th-127th)			
0	1	1	0	6 (32blocks, all)	6 (32blocks, block 32th-63th)	6 (64blocks, block 64th-127th)			
0	1	1	1	7 (32blocks, all)	7 (64blocks, all)	7 (128blocks, all)			
1	0	0	0	8 (32blocks, all)	8 (64blocks, all)	8 (128blocks, all)			
1	0	0	1	9 (32blocks, all)	9 (32blocks, block 0th-31th)	9 (64blocks, 0th-63th)			
1	0	1	0	10 (16blocks, block 0th-15th)	10 (48blocks, block 0th-47th)	10 (96blocks, block 0th-95th)			
1	0	1	1	11 (24blocks, block 0th-23th)	11 (56blocks, block 0th-55th)	11 (112blocks, block 0th-111th)			
1	1	0	0	12 (28blocks, block 0th-27th)	12 (60blocks, block 0th-59th)	12(120blocks, block 0th-119th)			
1	1	0	1	13 (30blocks, block 0th-29th)	13 (62blocks, block 0th-61th)	13(124blocks, block 0th-123th)			
1	1	1	0	14 (31blocks, block 0th-30th)	14 (63blocks, block 0th-62th)	14(126blocks, block 0th-125th)			
1	1	1	1	15 (32blocks, all)	15 (64blocks, all)	15 (128blocks, all)			

- **II.** Additional 512-bit secured OTP for unique identifier: to provide 512-bit one-time program area for setting device unique serial number Which may be set by factory or system customer. Please refer to table 3. 512-bit secured OTP definition.
- Security register bit 0 indicates whether the chip is locked by factory or not.
- To program the 512-bit secured OTP by entering 512-bit secured OTP mode (with ENSO command), and going through normal program procedure, and then exiting 512-bit secured OTP mode by writing EXSO command.
- Customer may lock-down the customer lockable secured OTP by writing WRSCUR(write security register) command to set customer lock-down bit1 as "1". Please refer to table of "security register definition" for security register bit definition and table of "512-bit secured OTP definition" for address range definition.
- Note: Once lock-down whatever by factory or customer, it cannot be changed any more. While in 512-bit secured OTP mode, array access is not allowed.

Table 3. 512-bit Secured OTP Definition

Address range	Size	Standard Factory Lock	Customer Lock
xxxx00~xxxx0F	128-bit	ESN (electrical serial number)	Determined by customer
xxxx10~xxxx3F	384-bit	N/A	

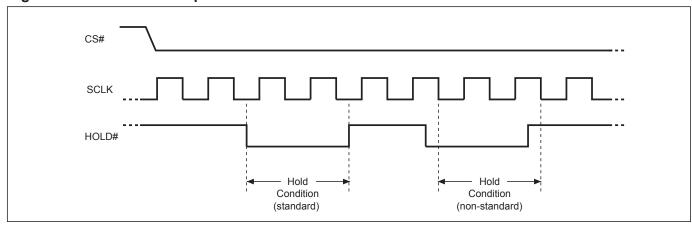


### **HOLD FEATURES**

HOLD# pin signal goes low to hold any serial communications with the device. The HOLD feature will not stop the operation of write status register, programming, or erasing in progress.

The operation of HOLD requires Chip Select(CS#) keeping low and starts on falling edge of HOLD# pin signal while Serial Clock (SCLK) signal is being low (if Serial Clock signal is not being low, HOLD operation will not start until Serial Clock signal being low). The HOLD condition ends on the rising edge of HOLD# pin signal while Serial Clock(SCLK) signal is being low( if Serial Clock signal is not being low, HOLD operation will not end until Serial Clock being low), see Figure 1.

**Figure 1. Hold Condition Operation** 



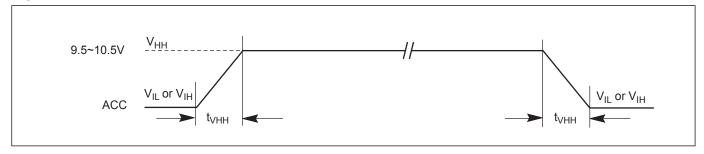
The Serial Data Output (SO) is high impedance, both Serial Data Input (SI) and Serial Clock (SCLK) are don't care during the HOLD operation. If Chip Select (CS#) drives high during HOLD operation, it will reset the internal logic of the device. To re-start communication with chip, the HOLD# must be at high and CS# must be at low.

### PROGRAM/ERASE ACCELERATION

To activate the program/erase acceleration function requires ACC pin connecting to 9.5~10.5V voltage (see Figure 2), and then to be followed by the normal program/erase process. By utilizing the program/erase acceleration operation, the performances are improved as shown on table of "ERASE AND PROGRAM PERFORMACE".

After power-up ready, it should wait 10ms at least to apply VHH(9.5~10.5V) on the WP#/ACC pin.

Figure 2. ACCELERATED PROGRAM TIMING DIAGRAM



Note: tVHH (VHH Rise and Fall Time) min. 250ns

# **Table 4. COMMAND DEFINITION**

Command (byte)	WREN (write enable)	WRDI (write disable)	RDID (read identific- ation)	RDSR (read status register)	WRSR (write status register)	READ (read data)	FAST READ (fast read data)	2READ (2 x I/O read command) Note1
1st byte	06 (hex)	04 (hex)	9F (hex)	05 (hex)	01 (hex)	03 (hex)	0B (hex)	BB (hex)
2nd byte						AD1	AD1	ADD(2)
3rd byte						AD2	AD2	ADD(2) & Dummy(2)
4th byte						AD3	AD3	
5th byte							Dummy	
Action	sets the (WEL) write enable latch bit	resets the (WEL) write enable latch bit	outputs JEDEC ID: 1-byte Manufact- urer ID & 2-byte Device ID	to read out the values of the status register	to write new values to the status register	n bytes read out until CS# goes high	n bytes read out until CS# goes high	

Note 1: The count base is 4-bit for ADD(2) and Dummy(2) because of 2 x I/O. And the MSB is on SI/SIO0 which is different from 1 x I/O condition.

					СР		RDP	
Command	SE (sector	BE (block	CE (chip	PP (page	(continuously	DP (Deep	(Release	RES (read
(byte)	erase)	erase)	erase)	program)	program	power down)	from deep	electronic ID)
					mode)		power down)	
1st byte	20 (hex)	D8 (hex)	60 or C7 (hex)	02 (hex)	AD (hex)	B9 (hex)	AB (hex)	AB (hex)
2nd byte	AD1	AD1		AD1	AD1			х
3rd byte	AD2	AD2		AD2	AD2			х
4th byte	AD3	AD3		AD3	AD3			х
5th byte								
	to erase the	to erase the	to erase	to program	continously	enters deep	release from	to read out
	selected	selected	whole chip	the selected	program	power down	deep power	1-byte Device
	sector	block		page	whole chip,	mode	down mode	ID
Action					the address			
					automatically			
					increases			

Note 2: ADD=00H will output the manufacturer ID first and ADD=01H will output device ID first.

Command (byte)	REMS (read electronic manufacturer & device ID)	REMS2 (read ID for 2x I/O mode)	ENSO (enter secured OTP)	EXSO (exit secured OTP)	RDSCUR (read security register)	WRSCUR (write security register)	ESRY (enable SO to output RY/ BY#)	DSRY (disable SO to output RY/ BY#)
1st byte	90 (hex)	EF (hex)	B1 (hex)	C1 (hex)	2B (hex)	2F (hex)	70 (hex)	80 (hex)
2nd byte	х	х						
3rd byte	Х	Х						
4th byte	ADD (Note 2)	ADD (Note 2)						
5th byte								
Action	output the Manufacturer ID & Device ID	output the Manufacturer ID & Device ID	to enter the 512-bit secured OTP mode	to exit the 512-bit secured OTP mode	to read value of security register	to set the lock-down bit as "1" (once lock-down, cannot be updated)	to enable SO to output RY/ BY# during CP mode	to disable SO to output RY/ BY# during CP mode

Note 3: It is not recommended to adopt any other code not in the command definition table, which will potentially enter the hidden mode.



Table 5-1. Memory Organization (16Mb)

S11	Block	Sector	Address	s Range
1		511	1FF000h	1FFFFFh
30	31	:	:	:
30		496	1F0000h	1F0FFFh
A80		495	1EF000h	1EFFFFh
29         479         1DF000h         1DFFFFh           ::::::::::::::::::::::::::::::::::::	30	:	:	:
29       479       1DF000h       1DFFFFh         ::::::::::::::::::::::::::::::::::::		480	1E0000h	1E0FFFh
A64				
28       463       1CF000h       1CFFFh         :       :       :       :         448       1C0000h       1C0FFFh         447       1BF000h       1BFFFFh         :       :       :       :         432       1B0000h       1B0FFFh         431       1AF000h       1AFFFFh         :       :       :       :         416       1A0000h       1A0FFFh         25       :       :       :         400       190000h       190FFFh         399       18F000h       18FFFFh         24       :       :       :         384       180000h       180FFFh         3384       180000h       170FFFh         3383       17F000h       170FFFh         24       :       :       :         368       170000h       170FFFh         22       :       :       :         367       16F000h       160FFFh         25       :       :       :         351       15F000h       150FFFh         20       :       :       :         336       150000h	29	:	:	:
28       463       1CF000h       1CFFFh         24       :       :       :         448       1C0000h       1C0FFFh         447       1BF000h       1BFFFFh         :       :       :         432       1B0000h       1B0FFFh         431       1AF000h       1AFFFFh         :       :       :         416       1A0000h       1A0FFFh         25       :       :       :         400       190000h       190FFFh         399       18F000h       18FFFFh         24       :       :       :         384       180000h       180FFFh         383       17F000h       17FFFFh         23       :       :       :         368       170000h       170FFFh         22       :       :       :         367       16F000h       16FFFFh         21       :       :       :         351       15F000h       15FFFh         20       :       :       :         336       150000h       140FFFh         39       13F000h       13FFFh		464	1D0000h	1D0FFFh
28         : : : : : : : : : : : : : : : : : : :				
27       447       1BF000h       1BFFFFh         ::::::::::::::::::::::::::::::::::::	28	:	:	:
27       447       1BF000h       1BFFFFh         ::::::::::::::::::::::::::::::::::::		448	1C0000h	1C0FFFh
18   18   18   18   18   18   18   18				
26       431       1AF000h       1AFFFFh         ::::::::::::::::::::::::::::::::::::	27	:	:	:
26       431       1AF000h       1AFFFFh         ::::::::::::::::::::::::::::::::::::		432	1B0000h	1B0FFFh
26				
1416	26		1/1/00011	·
25       415       19F000h       19FFFFh               400       190000h       190FFFh         399       18F000h       18FFFFh              384       180000h       180FFFh         383       17F000h       17FFFFh              368       170000h       170FFFh         22            367       16F000h       160FFFh         21            351       15F000h       15FFFh         21            336       150000h       150FFFh         20            335       14F000h       14FFFFh         20            320       140000h       140FFFh         39       13F000h       13FFFFh         303       12F000h       12FFFFh         288       120000h       120FFFh         287       11F000h       11FFFFh         272       110	20	116	100000	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
190000h				
190000h	25	415	19F000h	19FFFFN
24       399       18F000h       18FFFFh         384       180000h       180FFFh         383       17F000h       17FFFFh         368       170000h       170FFFh         367       16F000h       16FFFFh         22       352       160000h       160FFFh         351       15F000h       15FFFFh         21       336       150000h       150FFFh         20       335       14F000h       14FFFFh         20       320       140000h       140FFFh         319       13F000h       13FFFFh         304       130000h       130FFFh         303       12F000h       12FFFFh         288       120000h       120FFFh         17       287       11F000h       11FFFh         272       110000h       110FFFh         272       110000h       10FFFFh	25	<u>:</u>	:	:
24     :     :     :       384     180000h     180FFFh       383     17F000h     17FFFFh       :     :     :       368     170000h     170FFFh       22     :     :     :       367     16F000h     16FFFFh       :     :     :     :       352     160000h     160FFFh       21     :     :     :       336     15F000h     15FFFFh       20     :     :     :       335     14F000h     14FFFFh       20     :     :     :       320     140000h     140FFFh       319     13F000h     13FFFFh       304     130000h     130FFFh       303     12F000h     12FFFFh       :     :     :       288     120000h     120FFFh       17     :     :     :       272     110000h     110FFFh       16     :     :     :				
384		399	18F000h	18FFFFh
23   383   17F000h   17FFFFh	24	<u> </u>	:	:
368		384		180FFFh
368		383	17F000h	17FFFFh
22     367     16F000h     16FFFh       352     160000h     160FFFh       351     15F000h     15FFFFh       21     :     :     :       336     150000h     150FFFh       335     14F000h     14FFFFh       20     :     :     :       320     140000h     140FFFh       319     13F000h     13FFFFh       :     :     :       304     130000h     130FFFh       18     :     :       288     120000h     12FFFFh       17     :     :       287     11F000h     11FFFh       17     :     :       272     110000h     110FFFh       271     10F000h     10FFFFh       16     :     :	23	:	:	i i
22     : : : : : : : : : : : : : : : : : : :		368	170000h	170FFFh
352		367	16F000h	16FFFFh
351   15F000h   15FFFFh	22	:	:	:
21     : : : : : : : : : : : : : : : : : : :		352	160000h	160FFFh
21     : : : : : : : : : : : : : : : : : : :		351	15F000h	15FFFFh
336	21	:	:	:
20 335 14F000h 14FFFh 320 140000h 140FFFh 319 13F000h 13FFFFh 304 130000h 130FFFh 303 12F000h 12FFFFh 303 12F000h 12FFFFh 288 120000h 120FFFh 17 287 11F000h 11FFFFh 272 110000h 110FFFh 271 10F000h 10FFFFh 335 14F000h 120FFFh 340 120000h 120FFFh 35 120000h 120FFFh 36 12 120000h 110FFFh 37 11 10F000h 110FFFh 38 120000h 110FFFh 39 120000h 110FFFh		336	150000h	150FFFh
20 : : : : : : : : : : : : : : : : : : :				
320	20	:	: :: 300;;	:
19 319 13F000h 13FFFh  :: :: :: 304 130000h 130FFFh  303 12F000h 12FFFFh  :: :: :: 288 120000h 120FFFh  287 11F000h 11FFFFh  :: :: :: 272 110000h 110FFFh  16 :: :: ::		320	140000b	140FFFh
19 : : : : : : : : : : : : : : : : : : :				
18	19	:	:	:
18 303 12F000h 12FFFFh		304	130000b	130FFFh
18 : : : : : : : : : : : : : : : : : : :				
288 120000h 120FFFh  287 11F000h 11FFFFh  : : : : 272 110000h 110FFFh  271 10F000h 10FFFFh  16 : : :	40	303	12F000h	12FFFFh
17 287 11F000h 11FFFFh : : : : 272 110000h 110FFFh 271 10F000h 10FFFFh : : :	18	<u> </u>	:	<u> </u>
17 : : : : : : : : : : : : : : : : : : :		288	120000h	120FFFh
272 110000h 110FFFh 271 10F000h 10FFFFh 16 : :		287	11F000h	11FFFFh
16 271 10F000h 10FFFFh : :	17	:	<u> </u>	<u> </u>
16 : :		272	110000h	110FFFh
		271	10F000h	10FFFFh
	16	:	:	:
256   100000h   100FFFh		256	100000h	100FFFh

15	Block	Sector	Addres	s Range
240		255	0FF000h	0FFFFFh
14	15	:	:	:
14		240	0F0000h	0F0FFFh
14				
13	14	:	:	:
13		224	) : 0E0000b	) : OEOEEEh
13				
208	13			·
12	13	:	:	:
12				
192	40	207	0CF000h	UCFFFFN
191	12		:	:
11				
176		191	0BF000h	0BFFFFh
10	11	:	:	:
10		176	0B0000h	0B0FFFh
160		175	0AF000h	0AFFFFh
9	10	:	:	:
9		160	0A0000h	0A0FFFh
9				
144	9	155		
8		: 111	: 000000h	: 000FFFb
8				
128		143	08F000h	U8FFFFN
7         127         07F000h         07FFFFh           ::::::::::::::::::::::::::::::::::::	8	:	:	:
7 :: :: :: :: :: :: :: :: :: :: :: :: ::				
112 070000h 070FFFh  111 06F000h 06FFFFh  : : : :  96 060000h 060FFFh  95 05F000h 05FFFFh  : : : :  80 050000h 050FFFh  79 04F000h 04FFFh  64 040000h 040FFFh  3 : : :  48 030000h 030FFFh  2 : : : :  16 010000h 010FFFh  15 00F000h 004FFFh  15 00F000h 004FFFh  2 020000h 005FFFh  1 001000h 004FFFh  1 001000h 004FFFh		127	07F000h	07FFFFh
111 06F000h 06FFFh  :: :: :: :: :: :: :: :: :: :: :: :: ::	7	:	:	:
6 : : : : : : : : : : : : : : : : : : :		112	070000h	070FFFh
96 060000h 060FFFh 95 05F000h 05FFFFh  : : : : : : : : : : : : : : : : : : :		111	06F000h	06FFFFh
95     05F000h     05FFFh       ::     ::     ::       80     050000h     050FFFh       79     04F000h     04FFFh       ::     ::     ::       64     040000h     040FFFh       3     ::     ::       48     030000h     030FFFh       2     ::     ::       32     020000h     020FFFh       31     01F000h     01FFFh       ::     ::     ::       16     010000h     010FFFh       ::     ::     ::       4     004000h     004FFFh       2     002000h     002FFFh       1     001000h     001FFFh       2     002000h     002FFFh       1     001000h     001FFFh	6	:	:	:
95     05F000h     05FFFh       ::     ::     ::       80     050000h     050FFFh       79     04F000h     04FFFh       ::     ::     ::       64     040000h     040FFFh       3     ::     ::       48     030000h     030FFFh       2     ::     ::       32     020000h     020FFFh       31     01F000h     01FFFh       ::     ::     ::       16     010000h     010FFFh       ::     ::     ::       4     004000h     004FFFh       2     002000h     002FFFh       1     001000h     001FFFh       2     002000h     002FFFh       1     001000h     001FFFh		96	060000h	060FFFh
5         ::::::::::::::::::::::::::::::::::::				
80	5	- 33		
79  04F000h  04FFFh		:	: 050000h	:
4 :: : : : : : : : : : : : : : : : : :				
64         040000h         040FFFh           63         03F000h         03FFFFh           :         :         :           48         030000h         030FFFh           2         47         02F000h         02FFFFh           :         :         :         :           32         020000h         020FFFh           1         :         :         :           16         010000h         010FFFh           :         :         :         :           15         00F000h         00FFFFh           :         :         :           4         004000h         004FFFh           2         002000h         002FFFh           1         001000h         001FFFh			U4FUUUh	U4FFFFN
3	4	:	:	:
3 : : : : : : : : : : : : : : : : : : :				
48 030000h 030FFFh  47 02F000h 02FFFFh  2 : : : : :  32 020000h 020FFFh  31 01F000h 01FFFFh  : : : :  16 010000h 010FFFh  15 00F000h 00FFFh  : : : :  4 004000h 004FFFh  2 002000h 002FFFh  1 001000h 001FFFh	_	63	03F000h	03FFFFh
47     02F000h     02FFFFh       :     :     :       32     020000h     020FFFh       31     01F000h     01FFFh       :     :     :       16     010000h     010FFFh       :     :     :       4     004000h     004FFFh       2     002000h     002FFFh       1     001000h     001FFFh	3	<u>:</u>	<u> </u>	:
2 : : : : : : : : : : : : : : : : : : :		48	030000h	030FFFh
2 : : : : : : : : : : : : : : : : : : :		47	02F000h	02FFFFh
1 31 01F000h 01FFFh	2	:	: :	:
1 31 01F000h 01FFFh		32	020000h	020FFFh
1 : : : : : : : : : : : : : : : : : : :				
16 010000h 010FFFh  15 00F000h 00FFFFh  : : : :  4 004000h 004FFFh  2 002000h 002FFFh  1 001000h 001FFFh	1			
0 15 00F000h 00FFFh : : : : 4 004000h 004FFh 3 003000h 003FFFh 2 002000h 002FFFh 1 001000h 001FFFh	l '		100000	
0 3 003000h 003FFFh 2 002000h 002FFFh 1 001000h 001FFFh	<b>—</b>			
0 3 003000h 003FFFh 2 002000h 002FFFh 1 001000h 001FFFh		15	UUFUU0h	UUFFFFh
0 3 003000h 003FFFh 2 002000h 002FFFh 1 001000h 001FFFh		<u> </u>	:	:
2 002000h 002FFFh 1 001000h 001FFFh				
1 001000h 001FFFh	0		003000h	
		2	002000h	002FFFh
0 000000h 000FFFh		1	001000h	
		0	000000h	000FFFh

P/N: PM1290 REV. 1.5, APR. 29, 2009



Table 5-2. Memory Organization (32Mb)

Block	Sector	Addres	s Range
	1023	3FF000h	3FFFFFh
63	:	:	:
	1008	3F0000h	3F0FFFh
	1007	3EF000h	3EFFFFh
62	:	:	:
62	992	3E0000h	3E0FFFh
	991	3DF000h	3DFFFFh
61		3D1 00011	
01	: 070	:	:
	976	3D0000h 3CF000h	3D0FFFh
60	975	30500011	3CFFFFh
60	:	:	:
	960	3C0000h	3C0FFFh
	959	3BF000h	3BFFFFh
59		:	:
	944	3B0000h	3B0FFFh
	943	3AF000h	3AFFFFh
58	:	:	÷
	928	3A0000h	3A0FFFh
	927	39F000h	39FFFFh
57			
01	912	390000h	390FFFh
		<del>                                     </del>	
E6	911	38F000h	38FFFFh
56	:	:	:
	896	380000h	380FFFh
	895	37F000h	37FFFFh
55		:	:
	880	370000h	370FFFh
	879	36F000h	36FFFFh
54	:	:	:
	864	360000h	360FFFh
	863	35F000h	35FFFFh
53	:	:	:
00	: 848	: 250000h	: 250555b
		350000h	350FFFh
<b>5</b> 2	847	34F000h	34FFFFh
52	:	:	:
	832	340000h	340FFFh
F.4	831	33F000h	33FFFFh
51	<u> </u>	<u> </u>	:
	816	330000h	330FFFh
	815	32F000h	32FFFFh
50	:	:	:
	800	320000h	320FFFh
	799	31F000h	31FFFFh
49	:	:	:
_	: 784	310000h	310FFFh
		30F000h	30FFFFh
48	783	30-00011	
40	: :	:	:
l	768	l 300000h	300FFFh

Block	Sector	Address	s Range
	767	2FF000h	2FFFFFh
47	:	÷	÷
	752	2F0000h	2F0FFFh
	751	2EF000h	2EFFFFh
46	:	i i	÷
	736	2E0000h	2E0FFFh
	735	2DF000h	2DFFFFh
45	:	:	:
	720	2D0000h	2D0FFFh
	719	2CF000h	2CFFFFh
44	:	:	:
	704	2C0000h	2C0FFFh
	703	2BF000h	2BFFFFh
43	:	:	:
	688	2B0000h	2B0FFFh
	687	2AF000h	2AFFFFh
42	:	:	:
	672	2A0000h	2A0FFFh
	671	29F000h	29FFFFh
41	:	:	i i
	656	290000h	290FFFh
	655	28F000h	28FFFFh
40	:	:	:
	640	280000h	280FFFh
	639	27F000h	27FFFFh
39	:	:	i i
	624	270000h	270FFFh
	623	26F000h	26FFFFh
38	:	÷	÷
	608	260000h	260FFFh
	607	25F000h	25FFFFh
37	:	:	:
	592	250000h	250FFFh
	591	24F000h	24FFFFh
36	:	:	:
	576	240000h	240FFFh
	575	23F000h	23FFFFh
35	:	:	:
	560	230000h	230FFFh
	559	22F000h	22FFFFh
34	:	:	:
	<u>.</u> 544	220000h	220FFFh
	543	21F000h	21FFFFh
33	:	:	:
	: 528	: 210000h	: 210FFFh
	527	20F000h	20FFFFh
32	:	201 00011	;
	512	: 200000h	: 200FFFh
	312	20000011	ZUUFFFII





Section   Telegraph   Section   Telegraph	Block	Sector	Address Range				
31	DIOCK			•			
1	31	- 311	11 1 00011				
30	"	106	150000h	: 150555b			
180							
A80	20	495	1EF000h	1EFFFFN			
29         479         1DF000h         1DFFFFh           28         : : : : : : : : : : : : : : : : : : :	30	:	:	:			
29							
464         1D0000h         1D0FFFh           463         1CF000h         1CFFFh           28         : : : : : : : : : : : : : : : : : : :		479	1DF000h	1DFFFFh			
28       463       1CF000h       1CFFFFh         2448       1C0000h       1C0FFFh         447       1BF000h       1BFFFFh         27       : : : : : : : : : : : : : : : : : : :	29	:	:	:			
28         : : : : : : : : : : : : : : : : : : :							
A448		463	1CF000h	1CFFFFh			
27       447       1BF000h       1BFFFh         ::::::::::::::::::::::::::::::::::::	28	<u> </u>	:	:			
18   18   18   18   18   18   18   18		448	1C0000h	1C0FFFh			
A32		447	1BF000h	1BFFFFh			
26       431       1AF000h       1AFFFh               416       1A0000h       1A0FFFh         25       415       19F000h       19FFFFh               400       190000h       190FFFh         399       18F000h       18FFFFh              384       180000h       180FFFh         383       17F000h       17FFFFh              368       170000h       170FFFh         367       16F000h       16FFFFh              351       15F000h       15FFFFh              336       150000h       14FFFFh              335       14F000h       14FFFFh              304       130000h       130FFFh         303       12F000h       12FFFFh <td>27</td> <td>:</td> <td>:</td> <td>:</td>	27	:	:	:			
1416		432	1B0000h	1B0FFFh			
1416		431	1AF000h	1AFFFFh			
25       415       19F000h       19FFFh         ::::::::::::::::::::::::::::::::::::	26	:	:	:			
25       415       19F000h       19FFFh         ::::::::::::::::::::::::::::::::::::		416	1A0000h	1A0FFFh			
190000h							
190000h	25	:	:	:			
24     399     18F000h     18FFFh       384     180000h     180FFFh       383     17F000h     17FFFFh       23     : : : : : : : : : : : : : : : : : : :		400	190000h	100EEEh			
24       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :       :							
384	24		101-00011				
23     383     17F000h     17FFFh       368     170000h     170FFFh       367     16F000h     16FFFFh       22     : : : : : : : : : : : : : : : : : : :		:	:	:			
368							
368	22	383	17F000h	17FFFFN			
22     367     16F000h     16FFFh       352     160000h     160FFFh       351     15F000h     15FFFh       21     : : : : : : : : : : : : : : : : : : :	23	<u>:</u>	:	:			
22     : : : : : : : : : : : : : : : : : : :		368	170000h	1/0FFFh			
352		367	16F000h	16FFFFh			
351   15F000h   15FFFFh	22	:	:	÷			
21 : : : : : : : : : : : : : : : : : : :		352	160000h	160FFFh			
336		351	15F000h	15FFFFh			
20 335 14F000h 14FFFh  : : : 320 140000h 140FFFh  319 13F000h 13FFFFh  : : : 304 130000h 130FFFh  303 12F000h 12FFFFh  : : : 288 120000h 120FFFh  17 287 11F000h 11FFFFh  : : : 272 110000h 10FFFh  16 : : :	21	:	:	:			
20 335 14F000h 14FFFh  : : : 320 140000h 140FFFh  319 13F000h 13FFFFh  : : : 304 130000h 130FFFh  303 12F000h 12FFFFh  : : : 288 120000h 120FFFh  17 287 11F000h 11FFFFh  : : : 272 110000h 10FFFh  16 : : :		336	150000h	150FFFh			
20 : : : : : : : : : : : : : : : : : : :			i	14FFFFh			
19 319 13F000h 13FFFh  : : : 304 130000h 130FFFh  303 12F000h 12FFFFh  : : : 288 120000h 120FFFh  287 11F000h 11FFFFh  : : : 272 110000h 110FFFh  271 10F000h 10FFFFh  16 : : :	20	:	:	:			
19 319 13F000h 13FFFh  : : : 304 130000h 130FFFh  303 12F000h 12FFFFh  : : : 288 120000h 120FFFh  287 11F000h 11FFFFh  : : : 272 110000h 110FFFh  271 10F000h 10FFFFh  16 : : :		320	140000h	140FFFh			
19 : : : : : : : : : : : : : : : : : : :							
18 303 12F000h 12FFFFh : : : : 288 120000h 120FFFh 287 11F000h 11FFFFh : : : 272 110000h 110FFFh 271 10F000h 10FFFFh : : :	19	:	:	:			
18 303 12F000h 12FFFFh : : : : 288 120000h 120FFFh 287 11F000h 11FFFFh : : : 272 110000h 110FFFh 271 10F000h 10FFFFh : : :		304	130000h	130FFFh			
18 : : : : : : : : : : : : : : : : : : :							
288 120000h 120FFFh  287 11F000h 11FFFFh  : : : : 272 110000h 110FFFh  271 10F000h 10FFFFh  16 : : :	18		12500011	141777711			
287 11F000h 11FFFFh : : : : 272 110000h 110FFFh 271 10F000h 10FFFFh : : :	l 'Ŭ	300	1200006	120555			
17 : : : : : : : : : : : : : : : : : : :	<u> </u>						
272 110000h 110FFFh 271 10F000h 10FFFFh 16 : : :	47	287	11F000h	11FFFFh			
16 271 10F000h 10FFFFh : :	17	<u> </u>		:			
16 : :				110FFFh			
		271	10F000h	10FFFFh			
256 100000h 100FFFh	16	<u>:</u>	:	:			
		256	100000h	100FFFh			

Block	Sector	Addres	s Range
	255	0FF000h	0FFFFFh
15	:	:	:
	240	0F0000h	0F0FFFh
	239	0EF000h	0EFFFFh
14	:	:	:
''	224	0E0000h	0E0FFFh
	223	0DF000h	0DFFFFh
13	. 223		ODFFFFII
13	:	:	:
	208	0D0000h	0D0FFFh
40	207	0CF000h	0CFFFFh
12	:	:	:
	192	0C0000h	0C0FFFh
	191	0BF000h	0BFFFFh
11	l E	:	:
	176	0B0000h	0B0FFFh
	175	0AF000h	0AFFFFh
10	:	:	:
	160	0A0000h	0A0FFFh
	159	09F000h	09FFFFh
9	159		
	: 111	: 000000h	: 000FFFb
	144	090000h	090FFFh
	143	08F000h	08FFFFh
8	:	:	<u>:</u>
	128	080000h	080FFFh
	127	07F000h	07FFFFh
7	i i	:	:
	112	070000h	070FFFh
	111	06F000h	06FFFFh
6	:	:	:
	96	060000h	060FFFh
	95	05F000h	05FFFFh
5	:	:	:
	80	050000h	050FFFh
		04F000h	
4	79 ·		04FFFFh
l <sup>-</sup>	:	:	:
	64	040000h	040FFFh
	63	03F000h	03FFFFh
3	:	:	:
	48	030000h	030FFFh
	47	02F000h	02FFFFh
2	<u> </u>		
	32	020000h	020FFFh
	31	01F000h	01FFFFh
1	<del>- ;</del>	:	:
	16	010000h	010FFFh
	15	00F000h	00FFFFh
	:	:	:
_	4	004000h	004FFFh
0	3	003000h	003FFFh
	2	002000h	002FFFh
	1	001000h	001FFFh
	0	000000h	000FFFh



Table 5-3. Memory Organization (64Mb)

Block	Sector	Address Range			
Diook	2047	7FF000h	7FFFFFh		
127	:	:	:		
	2032	7F0000h	7F0FFFh		
	2032	7F0000h	7EFFFFh		
126	2031	1 1 1			
120	:	: - 7E0000b	:		
	2016 2015	7E0000h 7DF000h	7E0FFFh 7DFFFFh		
125	2015	7DF000N	/DEFEEII		
123	:	:	:		
	2000	7D0000h 7CF000h	7D0FFFh 7CFFFFh		
104	1999	7CF000h	/CFFFFN		
124	<u> </u>	:	:		
	1984	7C0000h	7C0FFFh		
	1983	7BF000h	7BFFFFh		
123		:	:		
	1968	7AF000h 7/ :: 7A0000h 7/ 79F000h 79 ::	7B0FFFh		
	1967	7AF000h	7AFFFFh		
122	:	:	:		
	1952	7A0000h	7A0FFFh		
	1951	79F000h	79FFFFh		
121	:	:	:		
	1936	790000h	790FFFh		
	1935	78F000h	78FFFFh		
120	1933	701 00011			
120	: 1920	780000h	: 780FFFh		
		<del> </del>			
119	1919	77F000h	77FFFFh		
119	:	:	:		
	1904	770000h	770FFFh		
	1903	76F000h	76FFFFh		
118	:	:	:		
	1888	760000h	760FFFh		
	1887	75F000h	75FFFFh		
117	:	:	:		
	1872	750000h	750FFFh		
	1871	74F000h	74FFFFh		
116		:	:		
	 1856	740000h	740FFFh		
	1855	73F000h	73FFFFh		
115	:	:	:		
	1840	730000h	: 730FFFh		
	1839	72F000h	72FFFFh		
114	<u> </u>	<u> </u>	:		
	1824	720000h	720FFFh		
	1823	71F000h	71FFFFh		
113	:	:	:		
	1808	710000h	710FFFh		
	1807	70F000h	70FFFFh		
112	:	:	:		
	<u>.</u> 1792	700000h	700FFFh		
		1	1		

Block	Sector	Addres	s Range
	1791	6FF000h	6FFFFFh
111	:	:	:
	1776	6F0000h	6F0FFFh
	1775	6EF000h	6EFFFFh
110	:	:	:
	1760	6E0000h	6E0FFFh
	1759	6DF000h	6DFFFFh
109	:	:	:
	1744	6D0000h	6D0FFFh
	1743	6CF000h	6CFFFFh
108	:	:	:
	1728	6C0000h	6C0FFFh
	1727	6BF000h	6BFFFFh
107	:	:	:
	1712	6B0000h	6B0FFFh
	1711	6AF000h	6AFFFFh
106	:	i i	i i
	1696	6A0000h	6A0FFFh
	1695	69F000h	69FFFFh
105	:	:	:
	1680	690000h	690FFFh
	1679	68F000h	68FFFFh
104	:	:	:
	1664	680000h	680FFFh
	1663	67F000h	67FFFFh
103	:	:	÷
	1648	670000h	670FFFh
	1647	66F000h	66FFFFh
102	:	:	:
	1632	660000h	660FFFh
	1631	65F000h	65FFFFh
101	:	:	:
		650000h	650FFFh
	1615	64F000h	64FFFFh
100	:	:	:
	1600	640000h	640FFFh
	1599	63F000h	63FFFFh
99	:	:	:
	1584	630000h	630FFFh
98	1583	62F000h	62FFFFh
30	1500	:	: 620EEE
	1568	620000h	620FFFh
97	1567	61F000h	61FFFFh
91	: 4550	:	:
	1552	610000h	610FFFh
06	1551	60F000h	60FFFFh
96	: 4500	:	:
	1536	600000h	600FFFh





Block	Sector	Address Range				
DIOCK	1535	5FF000h   5FFFFFh				
95	1000	311 00011	:			
	1520	5F0000h	: 5F0FFFh			
	1520		5EFFFFh			
94	1519	5EF000h	5EFFFF11			
34	:	:	:			
	1504	5E0000h	5E0FFFh			
93	1503	5DF000h	5DFFFFh			
93	:	:	:			
	1488	5D0000h	5D0FFFh			
00	1487	5CF000h	5CFFFFh			
92	:	:	:			
	1472	5C0000h	5C0FFFh			
0.4	1471	5BF000h	5BFFFFh			
91	<u> </u>	:	:			
	1456	5B0000h	5B0FFFh			
	1455	5AF000h	5AFFFFh			
90	:	:	:			
	1440	5A0000h	5A0FFFh			
	1439	59F000h	59FFFFh			
89	:	:	:			
	1424	590000h	590FFFh			
	1423	58F000h	58FFFFh			
88	:	:	:			
	1408	580000h	580FFFh			
	1407	57F000h	57FFFFh			
87	:	:	:			
	1392	570000h	570FFFh			
00	1391	56F000h	56FFFFh			
86	:	:	:			
	1376	560000h	560FFFh			
	1375	55F000h	55FFFFh			
85	:	:	:			
	1360	550000h	550FFFh			
	1359	54F000h	54FFFFh			
84	<u>:</u>	<u>:</u>	<u>:</u>			
	1344	540000h	540FFFh			
	1343	53F000h	53FFFFh			
83	:	:	:			
	1328	530000h	530FFFh			
	1327	52F000h	52FFFFh			
82	:	:	:			
	1312	520000h	520FFFh			
	1311	51F000h	51FFFFh			
81	:	:	:			
•	: 1296	: 510000h	: 510FFFh			
80	1295	50F000h	50FFFFh			
00	1000	:	:			
	1280	500000h	500FFFh			

Block	Sector	Addres	s Range
	1279	4FF000h	4FFFFFh
79	:	÷	:
	1264	4F0000h	4F0FFFh
	1263	4EF000h	4EFFFFh
78	:	i i	÷
	1248	4E0000h	4E0FFFh
	1247	4DF000h	4DFFFFh
77	:	÷	:
	1232	4D0000h	4D0FFFh
	1231	4CF000h	4CFFFFh
76	:	:	:
	1216	4C0000h	:: :: :: :: :: :: :: :: :: :: :: :: ::
	1215	4BF000h	4BFFFFh
75	:	÷	÷
	1200	4B0000h	4B0FFFh
	1119	4AF000h	4AFFFFh
74	:	:	:
	1184	4A0000h	4A0FFFh
	1183	49F000h	49FFFFh
73	:	:	:
	1168	490000h	490FFFh
	1167	48F000h	
72	:	:	:
	1152	480000h	480FFFh
	1151	47F000h	
71	:	:	:
	1136	470000h	470FFFh
	1135		
70	1133	+01 00011	
'	1120	: 460000h	: 460EEEh
	1119		
69	1119	45F00011	43555511
03	1104	: 450000b	: 450555b
68	1103	44F000H	+4111111
	1088	1400006	: 440EEEb
	1088		
67		43500011	+3FFFFII
01	1072	: 420000h	: 420EEEb
	1072		
60	1071	42F000h	42FFFFh
66	:	:	:
	1056	420000h	420FFFh
	1055	41F000h	41FFFFh
65	:	:	:
	1040	410000h	410FFFh
	1039	40F000h	40FFFFh
64	:	:	:
	1024	400000h	400FFFh





Block	Sector	Address Range			
	1023	3FF000h	3FFFFFh		
63	:	:	:		
	1008	3F0000h	3F0FFFh		
	1007	3EF000h	3EFFFFh		
62	:	:	:		
	992	3E0000h	3E0FFFh		
	991	3DF000h	3DFFFFh		
61	:	:	:		
	976	3D0000h	3D0FFFh		
	975	3CF000h	3CFFFFh		
60	- 373				
	: :	: 2C0000h	: 200555b		
	960 959	3C0000h 3BF000h	3C0FFFh 3BFFFFh		
59	959	36700011	SBFFFFII		
59	:	:	:		
	944		: : : : : : : : : : : : : : : : : : :		
	943	3AF000h	3AFFFFh		
58	:	i	i i		
	928	3A0000h	3A0FFFh		
	927	39F000h	39FFFFh		
57	:	:	:		
	912	390000h	390FFFh		
	911	38F000h	38FFFFh		
56	:	:	:		
	 896	380000h	380FFFh		
	895	37F000h	37FFFFh		
55	:	:	:		
	880	370000h	370FFFh		
<b>5</b> 4	879	36F000h	36FFFFh		
54	<u>:</u>	:	:		
	864	360000h	360FFFh		
	863	35F000h	35FFFFh		
53	<u>:</u>	:	:		
	848	350000h	350FFFh		
	847	34F000h	34FFFFh		
52		:	:		
	832	340000h	340FFFh		
	831	33F000h	33FFFFh		
51	:	:	:		
	816	330000h	330FFFh		
	815	32F000h	32FFFFh		
50					
30	: :	:	:		
	800	320000h	320FFFh		
	799	31F000h	31FFFFh		
49	:	:	:		
	784	310000h	310FFFh		
	783	30F000h	30FFFFh		
48	:	:	:		
	768	300000h	300FFFh		

Block	Sector	Address	s Range
	767	2FF000h	2FFFFFh
47	:	:	:
	752	2F0000h	2F0FFFh
	751	2EF000h	2EFFFFh
46	:	:	:
	736	2E0000h	2E0FFFh
	735	2DF000h	2DFFFFh
45	:	:	:
	720	2D0000h	2D0FFFh
	719	2CF000h	2CFFFFh
44	:	:	:
	704	2C0000h	2C0FFFh
	703	2BF000h	2BFFFFh
43	:	:	:
	688	2B0000h	2B0FFFh
	687	2AF000h	2AFFFFh
42	:	:	:
	672	2A0000h	2A0FFFh
	671	29F000h	29FFFFh
41	:	:	÷
	656	290000h	290FFFh
	655	28F000h	28FFFFh
40	:	:	:
	640	280000h	280FFFh
	639	27F000h	27FFFFh
39	÷	÷	÷
	624	270000h	270FFFh
	623	26F000h	26FFFFh
38	:	:	:
	608	260000h	260FFFh
	607	25F000h	25FFFFh
37	:	:	:
	<u>.</u> 592	250000h	250FFFh
	591	24F000h	24FFFFh
36	:	:	:
	<u>.</u> 576	240000h	240FFFh
	575	23F000h	23FFFFh
35	:	:	:
	560	230000h	230FFFh
	559	22F000h	22FFFFh
34	:	:	:
-	<u>:</u> 544	220000h	: 220FFFh
	543	21F000h	21FFFFh
33			
"	528	: 210000h	210EEEb
			210FFFh
32	527	20F000h	20FFFFh
] 52	: 540	3000005	:
	512	200000h	200FFFh





Block	Sector	Address Range			
	511	1FF000h	1FFFFFh		
31	:	:	:		
	496	1F0000h	1F0FFFh		
	495	1EF000h	1EFFFFh		
30	:	:	:		
	480	1E0000h	1E0FFFh		
	479	1DF000h	1DFFFFh		
29	:	:	:		
	464	1D0000h	1D0EEEh		
	463				
28	:	:	:		
	448	1C0000h	1C0EEEh		
	447				
27		101 00011			
	<u>:</u> 432	1P0000h	1B0555b		
			9F000h 19FFFh : : : : : : : : : : : : : : : : : : :		
0.0	431	1AF000h	1AFFFFh		
26		:	:		
	416	1A0000h			
	415	19F000h	19FFFFh		
25	:	:	:		
	400	190000h	190FFFh		
	399	18F000h	18FFFFh		
24	i i	:	:		
	384	180000h	180FFFh		
	383	17F000h	17FFFFh		
23	:	:	:		
	368	170000h	170FFFh		
	367	16F000h	16FFFFh		
22	:	:	:		
	352	160000h	160FFFh		
	351				
21		131 30011			
-	336	1500006	150555		
20	335	14F000h	14FFFFh		
20	:	:	:		
	320	140000h	140FFFh		
10	319	13F000h	13FFFFh		
19	<u> </u>		:		
	304	130000h	130FFFh		
	303	12F000h	12FFFFh		
18	:	:			
	288	120000h	120FFFh		
	287	11F000h	11FFFFh		
17	:	:	:		
	272	110000h	110FFFh		
	271	10F000h	10FFFFh		
16	:	:	:		
	256	100000h	: 100FFFh		
	230	10000011	10011111		

Block	Sector	Address	s Range
2.00.0	255	0FF000h	0FFFFFh
15	:	:	:
	240	0F0000h	0F0FFFh
	239		0EFFFFh
14	:	:	:
	224	0E0000h	OEOEEEh
	223		0DFFFFh
13	220	:	:
	208	0F0000h         0F0FF           0E7000h         0EFF           0E0000h         0EFF           0DF000h         0DFFF           0DF000h         0DFFF           0D0000h         0DFFF           0CF000h         0CFFF           0C0000h         0COFF           0BF000h         0BFFF           0BF000h         0BFFF           0AF000h         0AFFF           0AF000h         0AFFF           0AF000h         0AFFF           0BF000h         0BFF           0BF000h         0BFF <td>OD0EEEh</td>	OD0EEEh
	207		0CFFFFh
12			
'-	192	: 0C0000b	: OCOEEEh
	192		
11	191	OBFOOON .	OBFFFFN
''	:	:	:
	176		
4.0	175	0AF000h	0AFFFFh
10	<u> </u>	:	:
	160	0A0000h	0A0FFFh
	159	09F000h	09FFFFh
9		:	
	144	090000h	090FFFh
	143	08F000h	08FFFFh
8	:	:	:
	128	080000h	080FFFh
	127		07FFFFh
7	:	:	:
	112	070000h	070FFFh
	111		
6	- 111		
0	:	:	:
	96		
_	95	05F000h	05FFFFh
5		:	:
	80	050000h	050FFFh
	79	04F000h	04FFFFh
4		:	:
	64	040000h	040FFFh
	63	03F000h	03FFFFh
3		:	
	48	030000h	030FFFh
	47	02F000h	02FFFFh
2	:	:	:
	32	020000b	020FFFh
1	31		UIFFF[]
l '	:		:
	16		010FFFh
	15	00F000h	00FFFFh
	<u> </u>		:
_	4		004FFFh
0	3		003FFFh
	2	002000h	002FFFh
	1		001FFFh
	0	000000h	000FFFh

### **DEVICE OPERATION**

- Before a command is issued, status register should be checked to ensure device is ready for the intended operation.
- 2. When incorrect command is inputted to this LSI, this LSI becomes standby mode and keeps the standby mode until next CS# falling edge. In standby mode, SO pin of this LSI should be High-Z.
- 3. When correct command is inputted to this LSI, this LSI becomes active mode and keeps the active mode until next CS# rising edge.
- 4. Input data is latched on the rising edge of Serial Clock(SCLK) and data shifts out on the falling edge of SCLK. The difference of Serial mode 0 and mode 3 is shown as Figure 3.
- 5. For the following instructions: RDID, RDSR, RDSCUR, READ, FAST\_READ, 2READ, RES, REMS and REMS2 the shifted-in instruction sequence is followed by a data-out sequence. After any bit of data being shifted out, the CS# can be high. For the following instructions: WREN, WRDI, WRSR, SE, BE, CE, PP, CP, RDP, DP, ENSO, EXSO,and WRSCUR, the CS# must go high exactly at the byte boundary; otherwise, the instruction will be rejected and not executed.
- 6. During the progress of Write Status Register, Program, Erase operation, to access the memory array is neglected and not affect the current operation of Write Status Register, Program, Erase.

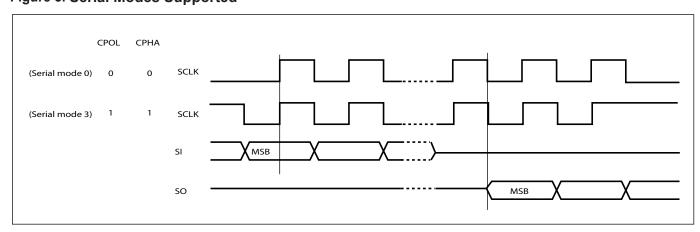


Figure 3. Serial Modes Supported

### Note

CPOL indicates clock polarity of Serial master, CPOL=1 for SCLK high while idle, CPOL=0 for SCLK low while not transmitting. CPHA indicates clock phase. The combination of CPOL bit and CPHA bit decides which Serial mode is supported.

### **COMMAND DESCRIPTION**

# (1) Write Enable (WREN)

The Write Enable (WREN) instruction is for setting Write Enable Latch (WEL) bit. For those instructions like PP, CP, SE, BE, CE, and WRSR, which are intended to change the device content, should be set every time after the WREN instruction setting the WEL bit.

The sequence of issuing WREN instruction is: CS# goes low→ sending WREN instruction code→ CS# goes high. (see Figure 12)

# (2) Write Disable (WRDI)

The Write Disable (WRDI) instruction is for resetting Write Enable Latch (WEL) bit.

The sequence of issuing WRDI instruction is: CS# goes low→ sending WRDI instruction code→ CS# goes high. (see Figure 13)

The WEL bit is reset by following situations:

- Power-up
- Write Disable (WRDI) instruction completion
- Write Status Register (WRSR) instruction completion
- Page Program (PP) instruction completion
- Sector Erase (SE) instruction completion
- Block Erase (BE) instruction completion
- Chip Erase (CE) instruction completion
- Continuously program mode (CP) instruction completion

# (3) Read Identification (RDID)

The RDID instruction is for reading the manufacturer ID of 1-byte and followed by Device ID of 2-byte. The MXIC Manufacturer ID is C2(hex), the memory type ID is 20(hex) as the first-byte device ID, and the individual device ID of second-byte ID are listed as table of "ID Definitions".

The sequence of issuing RDID instruction is: CS# goes low $\rightarrow$  sending RDID instruction code  $\rightarrow$  24-bits ID data out on SO  $\rightarrow$  to end RDID operation can use CS# to high at any time during data out. (see Figure. 14)

While Program/Erase operation is in progress, it will not decode the RDID instruction, so there's no effect on the cycle of program/erase operation which is currently in progress. When CS# goes high, the device is at standby stage.

# (4) Read Status Register (RDSR)

The RDSR instruction is for reading Status Register Bits. The Read Status Register can be read at any time (even in program/erase/write status register condition) and continuously. It is recommended to check the Write in Progress (WIP) bit before sending a new instruction when a program, erase, or write status register operation is in progress.

The sequence of issuing RDSR instruction is: CS# goes low→ sending RDSR instruction code→ Status Register data out on SO (see Figure. 15)

The definition of the status register bits is as below:

**WIP bit.** The Write in Progress (WIP) bit, a volatile bit, indicates whether the device is busy in program/erase/write status register progress. When WIP bit sets to 1, which means the device is busy in program/erase/write status register progress. When WIP bit sets to 0, which means the device is not in progress of program/erase/write status register cycle.

**WEL bit.** The Write Enable Latch (WEL) bit, a volatile bit, indicates whether the device is set to internal write enable latch. When WEL bit sets to 1, which means the internal write enable latch is set, the device can accept program/ erase/write status register instruction. When WEL bit sets to 0, which means no internal write enable latch; the device will not accept program/erase/write status register instruction. The program/erase command will be ignored and not affect value of WEL bit if it is applied to a protected memory area.

**BP3**, **BP2**, **BP1**, **BP0** bits. The Block Protect (BP3, BP2, BP1, BP0) bits, non-volatile bits, indicate the protected area(as defined in table 1) of the device to against the program/erase instruction without hardware protection mode being set. To write the Block Protect (BP3, BP2, BP1, BP0) bits requires the Write Status Register (WRSR) instruction to be executed. Those bits define the protected area of the memory to against Page Program (PP), Sector Erase (SE), Block Erase (BE) and Chip Erase(CE) instructions (only if all Block Protect bits set to 0, the CE instruction can be executed).

**Continuously Program Mode( CP mode) bit.** The Continuously Program Mode bit indicates the status of CP mode, "0" indicates not in CP mode; "1" indicates in CP mode.

**SRWD bit.** The Status Register Write Disable (SRWD) bit, non-volatile bit, is operated together with Write Protection (WP#/ACC) pin for providing hardware protection mode. The hardware protection mode requires SRWD sets to 1 and WP#/ACC pin signal is low stage. In the hardware protection mode, the Write Status Register (WRSR) instruction is no longer accepted for execution and the SRWD bit and Block Protect bits (BP3, BP2, BP1, BP0) are read only.

### Status Register

bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
SRWD	Continuously	BP3	BP2	BP1	BP0	WEL	WIP
(status register	program mode	(level of	(level of	(level of	(level of	(write enable	(write in
write protect)	(CP mode)	protected block)	protected block)	protected block)	protected block)	latch)	progress bit)
	0 = normal						1= write
1= status	program mode	(note1)	(note1)	(note1)	(note1)	1= write enable	operation
register write	1 = CP	(Hoter)	(Hote1)	(Hote I)	(Hote1)	0= not write	0= not in write
disable	mode(default 0)					enable	operation
Non-volatile bit	volatile bit	Non- volatile bit	Non- volatile bit	Non- volatile bit	Non- volatile bit	volatile bit	volatile bit

note1: see the table "Protected Area Sizes"

# (5) Write Status Register (WRSR)

The WRSR instruction is for changing the values of Status Register Bits. Before sending WRSR instruction, the Write Enable (WREN) instruction must be decoded and executed to set the Write Enable Latch (WEL) bit in advance. The WRSR instruction can change the value of Block Protect (BP3, BP2, BP1, BP0) bits to define the protected area of memory (as shown in table 1). The WRSR also can set or reset the Status Register Write Disable (SRWD) bit in accordance with Write Protection (WP#/ACC) pin signal. The WRSR instruction cannot be executed once the Hardware Protected Mode (HPM) is entered.

The sequence of issuing WRSR instruction is: CS# goes low→ sending WRSR instruction code→ Status Register data on SI→ CS# goes high. (see Figure 16)

The WRSR instruction has no effect on b6, b1, b0 of the status register.

The CS# must go high exactly at the byte boundary; otherwise, the instruction will be rejected and not executed. The self-timed Write Status Register cycle time (tW) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Write Status Register cycle is in progress. The WIP sets 1 during the tW timing, and sets 0 when Write Status Register Cycle is completed, and the Write Enable Latch (WEL) bit is reset.

**Table 6. Protection Modes** 

Mode	Status register condition	WP# and SRWD bit status	Memory
Software protection mode(SPM)	Status register can be written in (WEL bit is set to "1") and the SRWD, BP0-BP3 bits can be changed	WP#=1 and SRWD bit=0, or WP#=0 and SRWD bit=0, or WP#=1 and SRWD=1	The protected area cannot be program or erase.
Hardware protection mode (HPM)	The SRWD, BP0-BP3 of status register bits cannot be changed	WP#=0, SRWD bit=1	The protected area cannot be program or erase.

### Note:

1. As defined by the values in the Block Protect (BP3, BP2, BP1, BP0) bits of the Status Register, as shown in Table 1.

As the above table showing, the summary of the Software Protected Mode (SPM) and Hardware Protected Mode (HPM).

### Software Protected Mode (SPM):

- When SRWD bit=0, no matter WP#/ACC is low or high, the WREN instruction may set the WEL bit and can change the values of SRWD, BP3, BP2, BP1, BP0. The protected area, which is defined by BP3, BP2, BP1, BP0, is at software protected mode (SPM).
- When SRWD bit=1 and WP#/ACC is high, the WREN instruction may set the WEL bit can change the values of SRWD, BP3, BP2, BP1, BP0. The protected area, which is defined by BP3, BP2, BP1, BP0, is at software protected mode (SPM)



Note: If SRWD bit=1 but WP#/ACC is low, it is impossible to write the Status Register even if the WEL bit has previously been set. It is rejected to write the Status Register and not be executed.

Hardware Protected Mode (HPM):

- When SRWD bit=1, and then WP#/ACC is low (or WP#/ACC is low before SRWD bit=1), it enters the hardware protected mode (HPM). The data of the protected area is protected by software protected mode by BP3, BP2, BP1, BP0 and hardware protected mode by the WP#/ACC to against data modification.

Note: to exit the hardware protected mode requires WP#/ACC driving high once the hardware protected mode is entered. If the WP#/ACC pin is permanently connected to high, the hardware protected mode can never be entered; only can use software protected mode via BP3, BP2, BP1, BP0.

### (6) Read Data Bytes (READ)

The read instruction is for reading data out. The address is latched on rising edge of SCLK, and data shifts out on the falling edge of SCLK at a maximum frequency fR. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single READ instruction. The address counter rolls over to 0 when the highest address has been reached.

The sequence of issuing READ instruction is: CS# goes low→ sending READ instruction code→ 3-byte address on SI → data out on SO→ to end READ operation can use CS# to high at any time during data out. (see Figure. 17)

# (7) Read Data Bytes at Higher Speed (FAST\_READ)

The FAST\_READ instruction is for quickly reading data out. The address is latched on rising edge of SCLK, and data of each bit shifts out on the falling edge of SCLK at a maximum frequency fC. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single FAST\_READ instruction. The address counter rolls over to 0 when the highest address has been reached.

The sequence of issuing FAST\_READ instruction is: CS# goes low $\rightarrow$  sending FAST\_READ instruction code $\rightarrow$  3-byte address on SI $\rightarrow$  1-dummy byte address on SI $\rightarrow$ data out on SO $\rightarrow$  to end FAST\_READ operation can use CS# to high at any time during data out. (see Figure. 18)

While Program/Erase/Write Status Register cycle is in progress, FAST\_READ instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

### (8) 2 x I/O Read Mode (2READ)

The 2READ instruction enable double throughput of Serial Flash in read mode. The address is latched on rising edge of SCLK, and data of every two bits(interleave on 2 I/O pins) shift out on the falling edge of SCLK at a maximum frequency fT. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single 2READ instruction. The address counter rolls over to 0 when the highest address has been reached. Once writing 2READ instruction, the following address/dummy/data out will perform as 2-bit instead of previous 1-bit.

The sequence of issuing 2READ instruction is: CS# goes low $\rightarrow$  sending 2READ instruction $\rightarrow$  24-bit address interleave on SIO1 & SIO0 $\rightarrow$  8-bit dummy interleave on SIO1 & SIO0 $\rightarrow$  data out interleave on SIO1 & SIO0 $\rightarrow$  to end 2READ operation can use CS# to high at any time during data out (see Figure of 2 x I/O Read Mode Timing Waveform)



While Program/Erase/Write Status Register cycle is in progress, 2READ instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

The 2 I/O only perform read operation. Program/Erase /Read ID/Read status/Read ID....operation do not support 2 I/O throughputs.

# (9) Sector Erase (SE)

The Sector Erase (SE) instruction is for erasing the data of the chosen sector to be "1". The instruction is used for any 4K-byte sector. A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Sector Erase (SE). Any address of the sector (see table 3) is a valid address for Sector Erase (SE) instruction. The CS# must go high exactly at the byte boundary (the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

Address bits [Am-A12] (Am is the most significant address) select the sector address.

The sequence of issuing SE instruction is: CS# goes low  $\rightarrow$  sending SE instruction code $\rightarrow$  3-byte address on SI  $\rightarrow$  CS# goes high. (see Figure 22)

The self-timed Sector Erase Cycle time (tSE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Sector Erase cycle is in progress. The WIP sets 1 during the tSE timing, and sets 0 when Sector Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP3, BP2, BP1, BP0 bits, the Sector Erase (SE) instruction will not be executed on the page.

### (10) Block Erase (BE)

The Block Erase (BE) instruction is for erasing the data of the chosen block to be "1". The instruction is used for 64K-byte sector erase operation. A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Block Erase (BE). Any address of the block (see table 3) is a valid address for Block Erase (BE) instruction. The CS# must go high exactly at the byte boundary (the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

The sequence of issuing BE instruction is: CS# goes low  $\rightarrow$  sending BE instruction code $\rightarrow$  3-byte address on SI  $\rightarrow$  CS# goes high. (see Figure 23)

The self-timed Block Erase Cycle time (tBE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Sector Erase cycle is in progress. The WIP sets 1 during the tBE timing, and sets 0 when Sector Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP3, BP2, BP1, BP0 bits, the Block Erase (BE) instruction will not be executed on the page.

### (11) Chip Erase (CE)

The Chip Erase (CE) instruction is for erasing the data of the whole chip to be "1". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Chip Erase (CE). Any address of the sector (see table 3) is a valid address for Chip Erase (CE) instruction. The CS# must go high exactly at the byte boundary( the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

The sequence of issuing CE instruction is: CS# goes low $\rightarrow$  sending CE instruction code $\rightarrow$  CS# goes high. (see Figure 24)



The self-timed Chip Erase Cycle time (tCE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Chip Erase cycle is in progress. The WIP sets 1 during the tCE timing, and sets 0 when Chip Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the chip is protected by BP3, BP2, BP1, BP0 bits, the Chip Erase (CE) instruction will not be executed. It will be only executed when BP3, BP2, BP1, BP0 all set to "0".

# (12) Page Program (PP)

The Page Program (PP) instruction is for programming the memory to be "0". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Page Program (PP). If the eight least significant address bits (A7-A0) are not all 0, all transmitted data which goes beyond the end of the current page are programmed from the start address if the same page (from the address whose 8 least significant address bits (A7-A0) are all 0). The CS# must keep during the whole Page Program cycle. The CS# must go high exactly at the byte boundary( the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed. If more than 256 bytes are sent to the device, the data of the last 256-byte is programmed at the request page and previous data will be disregarded. If less than 256 bytes are sent to the device, the data is programmed at the request address of the page without effect on other address of the same page.

The sequence of issuing PP instruction is: CS# goes low $\rightarrow$  sending PP instruction code $\rightarrow$  3-byte address on SI $\rightarrow$  at least 1-byte on data on SI $\rightarrow$  CS# goes high. (see Figure 20)

The self-timed Page Program Cycle time (tPP) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Page Program cycle is in progress. The WIP sets 1 during the tPP timing, and sets 0 when Page Program Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP3, BP2, BP1, BP0 bits, the Page Program (PP) instruction will not be executed.

### (13) Continuously program mode (CP mode)

The CP mode may enhance program performance by automatically increasing address to the next higher address after each byte data has been programmed.

The Continuously program (CP) instruction is for multiple byte program to Flash. A write Enable (WREN) instruction must execute to set the Write Enable Latch(WEL) bit before sending the Continuously program (CP) instruction. CS# requires to go high before CP instruction is executing. After CP instruction and address input, two bytes of data is input sequentially from MSB(bit7) to LSB(bit0). The first byte data will be programmed to the initial address range with A0=0 and second byte data with A0=1. If only one byte data is input, the CP mode will not process. If more than two bytes data are input, the additional data will be ignored and only two byte data are valid. The CP program instruction will be ignored and not affect the WEL bit if it is applied to a protected memory area. Any byte to be programmed should be in the erase state (FF) first. It will not roll over during the CP mode, once the last unprotected address has been reached, the chip will exit CP mode and reset write Enable Latch bit (WEL) as "0" and CP mode bit as "0". Please check the WIP bit status if it is not in write progress before entering next valid instruction. During CP mode, the valid commands are CP command (AD hex), WRDI command (04 hex), RDSR command (05 hex), RDPR command (A1 hex), and RDSCUR command (2B hex). And the WRDI command is valid after completion of a CP programming cycle, which means the WIP bit=0.

The sequence of issuing CP instruction is: CS# high to low $\rightarrow$  sending CP instruction code $\rightarrow$  3-byte address on SI $\rightarrow$  Data Byte on SI $\rightarrow$ CS# goes high to low $\rightarrow$  sending CP instruction..... $\rightarrow$  last desired byte programmed or sending Write Disable (WRDI) instruction to end CP mode $\rightarrow$  sending RDSR instruction to verify if CP mode is ended. (see Figure of CP mode timing waveform)

Three methods to detect the completion of a program cycle during CP mode:



- 1) Software method-I: by checking WIP bit of Status Register to detect the completion of CP mode.
- Software method-II: by waiting for a tBP time out to determine if it may load next valid command or not.
- 3) Hardware method: by writing ESRY (enable SO to output RY/BY#) instruction to detect the completion of a program cycle during CP mode. The ESRY instruction must be executed before CP mode execution. Once it is enable in CP mode, the CS# goes low will drive out the RY/BY# status on SO, "0" indicates busy stage, "1" indicates ready stage, SO pin outputs tri-state if CS# goes high. DSRY (disable SO to output RY/BY#) instruction to disable the SO to output RY/BY# and return to status register data output during CP mode. Please note that the ESRY/DSRY command are not accepted unless the completion of CP mode.

# (14) Deep Power-down (DP)

The Deep Power-down (DP) instruction is for setting the device on the minimizing the power consumption (to entering the Deep Power-down mode), the standby current is reduced from ISB1 to ISB2). The Deep Power-down mode requires the Deep Power-down (DP) instruction to enter, during the Deep Power-down mode, the device is not active and all Write/Program/Erase instruction are ignored. When CS# goes high, it's only in standby mode not deep power-down mode. It's different from Standby mode.

The sequence of issuing DP instruction is: CS# goes low→ sending DP instruction code→ CS# goes high. (see Figure 25)

Once the DP instruction is set, all instruction will be ignored except the Release from Deep Power-down mode (RDP) and Read Electronic Signature (RES) instruction. (those instructions allow the ID being reading out). When Power-down, the deep power-down mode automatically stops, and when power-up, the device automatically is in standby mode. For RDP instruction the CS# must go high exactly at the byte boundary (the latest eighth bit of instruction code been latched-in); otherwise, the instruction will not executed. As soon as Chip Select (CS#) goes high, a delay of tDP is required before entering the Deep Power-down mode and reducing the current to ISB2.

# (15) Release from Deep Power-down (RDP), Read Electronic Signature (RES)

The Release from Deep Power-down (RDP) instruction is terminated by driving Chip Select (CS#) High. When Chip Select (CS#) is driven High, the device is put in the Stand-by Power mode. If the device was not previously in the Deep Power-down mode, the transition to the Stand-by Power mode is immediate. If the device was previously in the Deep Power-down mode, though, the transition to the Stand-by Power mode is delayed by tRES2, and Chip Select (CS#) must remain High for at least tRES2(max), as specified in Table 6. Once in the Stand-by Power mode, the device waits to be selected, so that it can receive, decode and execute instructions.

RES instruction is for reading out the old style of 8-bit Electronic Signature, whose values are shown as table of ID Definitions. This is not the same as RDID instruction. It is not recommended to use for new design. For new design, please use RDID instruction. Even in Deep power-down mode, the RDP and RES are also allowed to be executed, only except the device is in progress of program/erase/write cycle; there's no effect on the current program/erase/write cycle in progress.

The sequence is shown as Figure 26,27.

The RES instruction is ended by CS# goes high after the ID been read out at least once. The ID outputs repeatedly if continuously send the additional clock cycles on SCLK while CS# is at low. If the device was not previously in Deep Power-down mode, the device transition to standby mode is immediate. If the device was previously in Deep Power-down mode, there's a delay of tRES2 to transit to standby mode, and CS# must remain to high at least tRES2(max). Once in the standby mode, the device waits to be selected, so it can be receive, decode, and execute instruction.

The RDP instruction is for releasing from Deep Power Down Mode.

### (16) Read Electronic Manufacturer ID & Device ID (REMS), (REMS2)

The REMS & REMS2 instruction is an alternative to the Release from Power-down/Device ID instruction that provides both the JEDEC assigned manufacturer ID and the specific device ID.

The REMS & REMS2 instruction is very similar to the Release from Power-down/Device ID instruction. The instruction is initiated by driving the CS# pin low and shift the instruction code "90h" or "EFh" followed by two dummy bytes and one bytes address (A7~A0). After which, the Manufacturer ID for MXIC (C2h) and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in figure 25. The Device ID values are listed in Table of ID Definitions. If the one-byte address is initially set to 01h, then the device ID will be read first and then followed by the Manufacturer ID. The Manufacturer and Device IDs can be read continuously, alternating from one to the other. The instruction is completed by driving CS# high.

**Table 7. ID Definitions** 

Command Type MX25L1605D			MX25L3205D			MX25L6405D				
RDID Command	manufacturer ID	memory type	memory density	manufacturer ID	memory type	memory density	manufacturer ID	memory type	memory density	
	C2	20	15	C2	20	16	C2	20	17	
RES Command	electronic ID			electronic ID			electronic ID			
RES Command		14			15			16		
REMS/REMS2	manufacturer ID	device ID		manufacturer ID	device ID		manufacturer ID	device ID		
	C2	14		C2	15		C2	16		

### (17) Enter Secured OTP (ENSO)

The ENSO instruction is for entering the additional 512-bit secured OTP mode. The additional 512-bit secured OTP is independent from main array, which may use to store unique serial number for system identifier. After entering the Secured OTP mode, and then follow standard read or program, procedure to read out the data or update data. The Secured OTP data cannot be updated again once it is lock-down.

The sequence of issuing ENSO instruction is: CS# goes low $\rightarrow$  sending ENSO instruction to enter Secured OTP mode  $\rightarrow$  CS# goes high.

Please note that WRSR/WRSCUR commands are not acceptable during the access of secure OTP region, once security OTP is lock down, only read related commands are valid.

### (18) Exit Secured OTP (EXSO)

The EXSO instruction is for exiting the additional 512-bit secured OTP mode.

The sequence of issuing EXSO instruction is: CS# goes low $\rightarrow$  sending EXSO instruction to exit Secured OTP mode $\rightarrow$  CS# goes high.

# (19) Read Security Register (RDSCUR)

The RDSCUR instruction is for reading the value of Security Register bits. The Read Security Register can be read at any time (even in program/erase/write status register/write security register condition) and continuously.

The sequence of issuing RDSCUR instruction is : CS# goes low $\rightarrow$  send ing RDSCUR instruction  $\rightarrow$  Security Register data out on SO $\rightarrow$  CS# goes high.

The definition of the Security Register bits is as below:

**Secured OTP Indicator bit.** The Secured OTP indicator bit shows the chip is locked by factory before ex- factory or not. When it is "0", it indicates non- factory lock; "1" indicates factory- lock.

**Lock-down Secured OTP (LDSO) bit.** By writing WRSCUR instruction, the LDSO bit may be set to "1" for customer lock-down purpose. However, once the bit is set to "1" (lock-down), the LDSO bit and the 512-bit Secured OTP area cannot be update any more. While it is in 512-bit secured OTP mode, array access is not allowed.

**Table 8. Security Register Definition** 

bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
х	х	х	х	×	х	LDSO (indicate if lock-down	Secrured OTP indicator bit
reserved	reserved	reserved	reserved	reserved	reserved	0 = not lock- down 1 = lock-down (cannot program/erase OTP)	0 = non- factory lock 1 = factory lock
volatile bit	non-volatile bit	non-volatile bit					

# (20) Write Security Register (WRSCUR)

The WRSCUR instruction is for changing the values of Security Register Bits. Unlike write status register, the WREN instruction is not required before sending WRSCUR instruction. The WRSCUR instruction may change the values of bit1 (LDSO bit) for customer to lock-down the 512-bit Secured OTP area. Once the LDSO bit is set to "1", the Secured OTP area cannot be updated any more.

The sequence of issuing WRSCUR instruction is :CS# goes low $\rightarrow$  sending WRSCUR instruction  $\rightarrow$  CS# goes high.

The CS# must go high exactly at the boundary; otherwise, the instruction will be rejected and not executed.

### **POWER-ON STATE**

The device is at below states when power-up:

- Standby mode (please note it is not deep power-down mode)
- Write Enable Latch (WEL) bit is reset

The device must not be selected during power-up and power-down stage unless the VCC achieves below correct level:

- VCC minimum at power-up stage and then after a delay of tVSL
- GND at power-down

Please note that a pull-up resistor on CS# may ensure a safe and proper power-up/down level.

An internal power-on reset (POR) circuit may protect the device from data corruption and inadvertent data change during power up state.

For further protection on the device, if the VCC does not reach the VCC minimum level, the correct operation is not guaranteed. The read, write, erase, and program command should be sent after the below time delay:

- tVSL after VCC reached VCC minimum level

The device can accept read command after VCC reached VCC minimum and a time delay of tVSL. Please refer to the figure of "power-up timing".

#### Note

- To stabilize the VCC level, the VCC rail decoupled by a suitable capacitor close to package pins is recommended.(generally around 0.1uF)



### **ELECTRICAL SPECIFICATIONS**

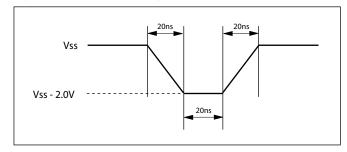
### **ABSOLUTE MAXIMUM RATINGS**

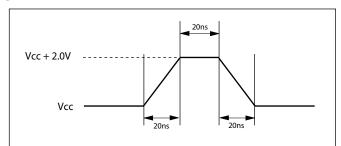
RATING	VALUE
Ambient Operating Temperature	-40°C to 85°C for Industrial grade
Storage Temperature	-55°C to 125°C
Applied Input Voltage	-0.5V to 4.6V
Applied Output Voltage	-0.5V to 4.6V
VCC to Ground Potential	-0.5V to 4.6V

### NOTICE:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is stress rating only and functional operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended period may affect reliability.
- 2. Specifications contained within the following tables are subject to change.
- 3. During voltage transitions, all pins may overshoot Vss to -2.0V and Vcc to +2.0V for periods up to 20ns, see Figure 4, 5.

Figure 4.Maximum Negative Overshoot Waveform Figure 5. Maximum Positive Overshoot Waveform





# CAPACITANCE TA = 25°C, f = 1.0 MHz

SYMBOL	PARAMETER	MIN.	TYP	MAX.	UNIT	CONDITIONS
CIN	Input Capacitance			6	pF	VIN = 0V
COUT	Output Capacitance			8	pF	VOUT = 0V



# Figure 6. INPUT TEST WAVEFORMS AND MEASUREMENT LEVEL

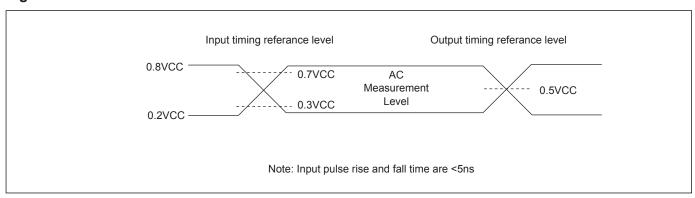
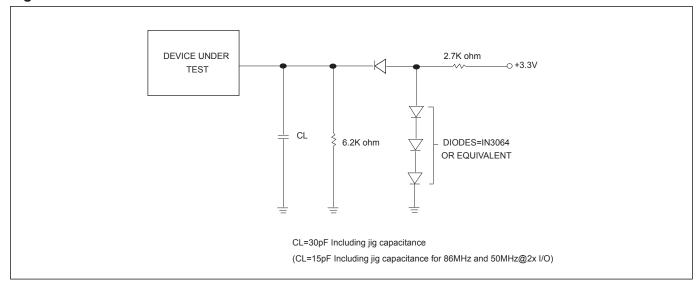


Figure 7. OUTPUT LOADING



# Table 9. DC CHARACTERISTICS (Temperature = -40°C to 85°C for Industrial grade, VCC = 2.7V ~ 3.6V)

SYMBOL	PARAMETER	NOTES	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
ILI	Input Load Current	1			± 2	uA	VCC = VCC Max, VIN = VCC or GND
ILO	Output Leakage Current	1			± 2	uA	VCC = VCC Max, VIN = VCC or GND
ILIHV	HV pin input Leakage Current				35	uA	WP#/ACC=10.5V
ISB1	VCC Standby Current	1			20	uA	VIN = VCC or GND, CS# = VCC
ISB2	Deep Power-down Current				20	uA	VIN = VCC or GND, CS# = VCC
					25	mA	f=86MHz fT=50MHz (2 x I/O read) SCLK=0.1VCC/0.9VCC, SO=Open
ICC1	VCC Read	1			20	mA	f=66MHz, SCLK=0.1VCC/0.9VCC, SO=Open
					10	mA	f=33MHz, SCLK=0.1VCC/0.9VCC, SO=Open
ICC2	VCC Program Current (PP)	1			20	mA	Program in Progress, CS# = VCC
ICC3	VCC Write Status Register (WRSR) Current				20	mA	Program status register in progress, CS#=VCC
ICC4	VCC Sector Erase Current (SE)	1			20	mA	Erase in Progress, CS#=VCC
ICC5	VCC Chip Erase Current (CE)	1			20	mA	Erase in Progress, CS#=VCC
VHH	Voltage for ACC Program/ Erase Acceleration		9.5		10.5	V	VCC=2.7V~3.6V
VIL	Input Low Voltage		-0.5		0.3VCC	V	
VIH	Input High Voltage		0.7VCC		VCC+0.4	V	
VOL	Output Low Voltage				0.4	V	IOL = 1.6mA
VOH	Output High Voltage		VCC-0.2			V	IOH = -100uA



Table 10. AC CHARACTERISTICS (Temperature = -40°C to 85°C for Industrial grade, VCC = 2.7V ~ 3.6V)

Symbol	Alt.	Parameter			Min.	Тур.	Max.	Unit
		Clock Frequency for the fol			10KHz		86 (Condition:15pF)	MHz
fSCLK	fC	FAST_READ, PP, SE, BE,		,RDP			66	
		WREN, WRDI, RDID, RDS	R, WRSR				(Condition:30pF)	MHz
fRSCLK	fR	Clock Frequency for READ	instructions		10KHz		33	MHz
fTSCLK	fT	Clock Frequency for 2REA	D instructions	3	10KHz		50	MHz
ITSULK							(Condition:15pF)	
tCH(1)	tCLH	Clock High Time		fc=86MHz	5.5			ns
1011(1)	tolii	Clock Flight Flitte		fR=33MHz	13			ns
tCL(1)	tCLL	Clock Low Time		fc=86MHz	5.5 13			ns
	TOLL		fR=33MHz					ns
tCLCH(2)		Clock Rise Time (3) (peak t			0.1			V/ns
tCHCL(2)		Clock Fall Time (3) (peak to	<u> </u>		0.1			V/ns
tSLCH	tCSS	CS# Active Setup Time (rel		5			ns	
tCHSL		CS# Not Active Hold Time	(relative to So	5			ns	
tDVCH	<del> </del>	Data In Setup Time		2			ns	
tCHDX	tDH	Data In Hold Time		5			ns	
tCHSH		CS# Active Hold Time (rela	5			ns		
tSHCH		CS# Not Active Setup Time	5			ns		
tSHSL	tCSH	CS# Deselect Time			40			ns
		tDIS Output Disable Time	64Mb/	2.7V-3.6V			10	ns
tSHQZ(2)	tDIS		32Mb/ 16Mb	3.0V-3.6V			8	ns
		Clock Low to Output Valid	64Mb/	2.7V-3.6V			10	ns
tCLQV	tV	Clock Low to Output valid	32Mb/ 16Mb	3.0V-3.6V			8	ns
tCLQX	tHO	Output Hold Time	•	•	0			ns
tHLCH		HOLD# Setup Time (relativ	e to SCLK)		5			ns
tCHHH		HOLD# Hold Time (relative	to SCLK)		5			ns
tHHCH		<b>HOLD Setup Time (relative</b>	to SCLK)		5			ns
tCHHL		HOLD Hold Time (relative t	o SCLK)		5			ns
tHHQX(2)	tLZ		64Mb/	2.7V-3.6V			10	ns
		HOLD to Output Low-Z	32Mb/ 16Mb	3.0V-3.6V			8	ns
tHLQZ(2)	tHZ		64Mb/	2.7V-3.6V			10	ns
	li iZ	HOLD# to Output High-Z	32Mb/	3.0V-3.6V			8	ns
		110LD# to Output High-Z	16Mb	3.00-3.00			0	115
tWHSL(4)		Write Protect Setup Time						ns
tSHWL (4)		Write Protect Hold Time	100			ns		
tDP(2)		CS# High to Deep Power-down Mode					10	us
tRES1(2)		CS# High to Standby Mode without Electronic Signature Read					8.8	us
tRES2(2)		CS# High to Standby Mode with Electronic Signature Read					8.8	us

Symbol	Alt.	Parameter		Min.	Тур.	Max.	Unit
tW		Write Status Register Cycle Time	Status Register Cycle Time		40	100	ms
tBP		Byte-Program	rogram		9	300	us
tPP		Page Program Cycle Time		1.4	5	ms	
tSE		Sector Erase Cycle Time			60	300	ms
tBE		Block Erase Cycle Time			0.7	2	S
			64Mb		50	80	S
tCE	tCE	Chip Erase Cycle Time	32Mb		25	50	S
			16Mb		14	30	S

#### Notes

- 1. tCH + tCL must be greater than or equal to 1/ fC. For Fast Read, tCL/tCH=5.5/5.5.
- 2. Value guaranteed by characterization, not 100% tested in production.
- 3. Expressed as a slew-rate.
- 4. Only applicable as a constraint for a WRSR instruction when SRWD is set at 1.
- 5. Test condition is shown as Figure 6.

# **Table 11. Power-Up Timing**

Symbol	Parameter	Min.	Max.	Unit
tVSL(1)	VCC(min) to CS# low	200		us

Note: 1. The parameter is characterized only.

# **INITIAL DELIVERY STATE**

The device is delivered with the memory array erased: all bits are set to 1 (each byte contains FFh). The Status Register contains 00h (all Status Register bits are 0).



Figure 8. Serial Input Timing

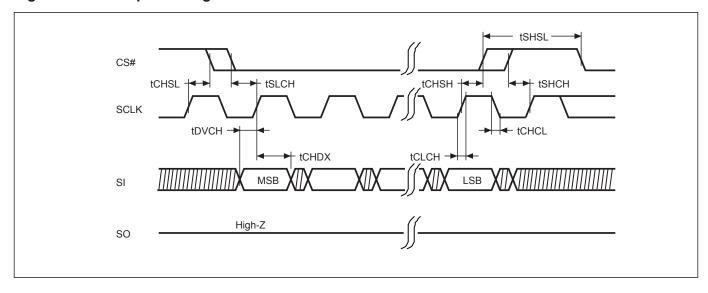
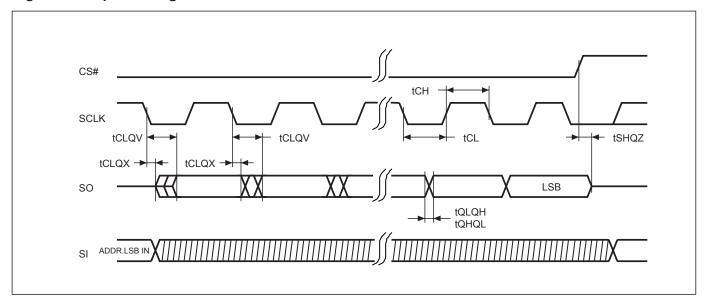
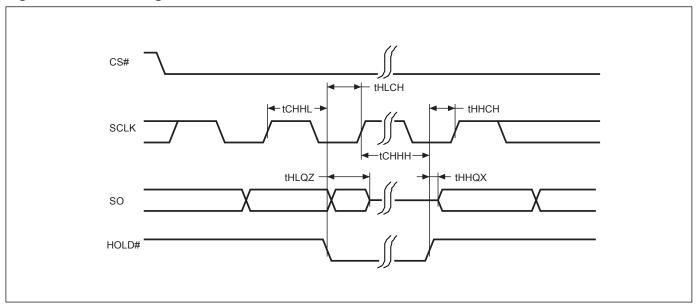


Figure 9. Output Timing





# Figure 10. Hold Timing



<sup>\*</sup> SI is "don't care" during HOLD operation.

Figure 11. WP# Disable Setup and Hold Timing during WRSR when SRWD=1

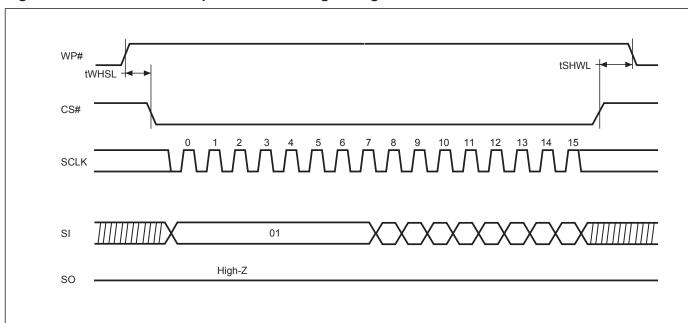




Figure 12. Write Enable (WREN) Sequence (Command 06)

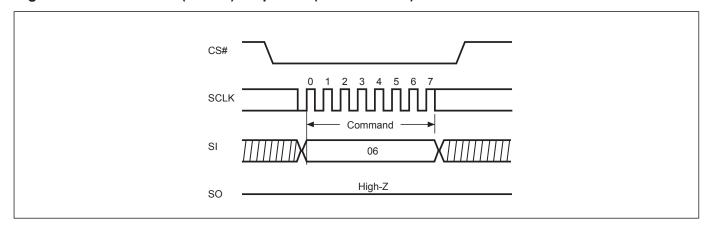


Figure 13. Write Disable (WRDI) Sequence (Command 04)

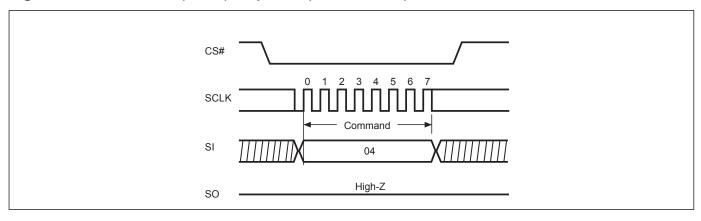


Figure 14. Read Identification (RDID) Sequence (Command 9F)

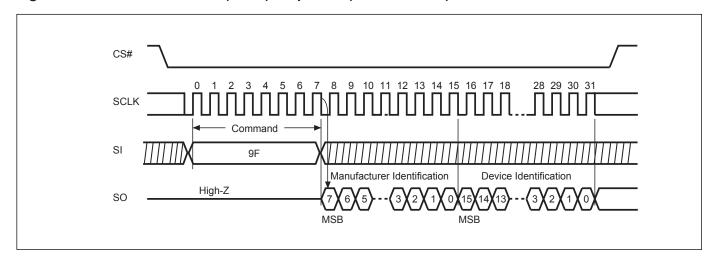




Figure 15. Read Status Register (RDSR) Sequence (Command 05)

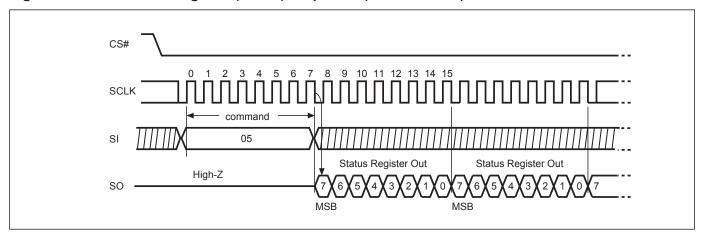


Figure 16. Write Status Register (WRSR) Sequence (Command 01)

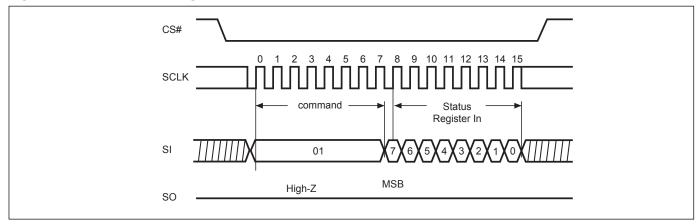


Figure 17. Read Data Bytes (READ) Sequence (Command 03)

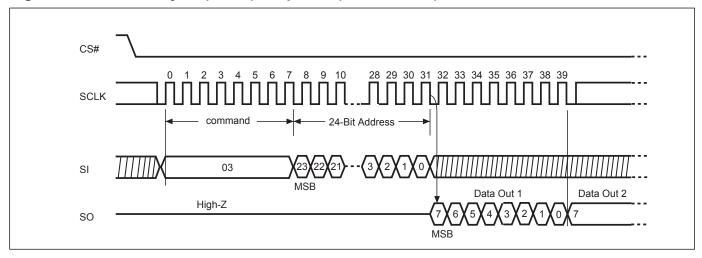




Figure 18. Read at Higher Speed (FAST\_READ) Sequence (Command 0B)

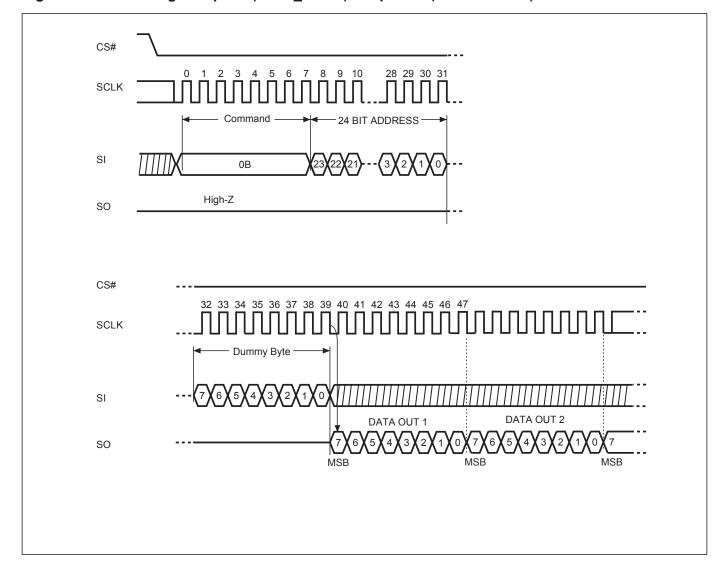




Figure 19. 2 x I/O Read Mode Sequence (Command BB)

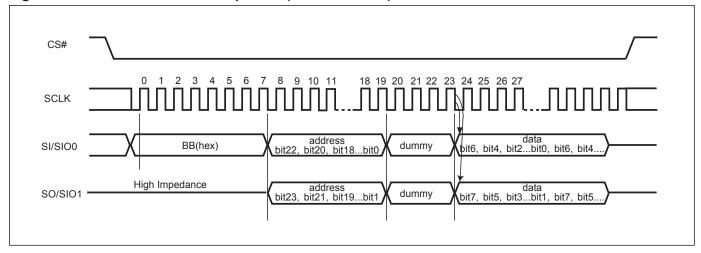


Figure 20. Page Program (PP) Sequence (Command 02)

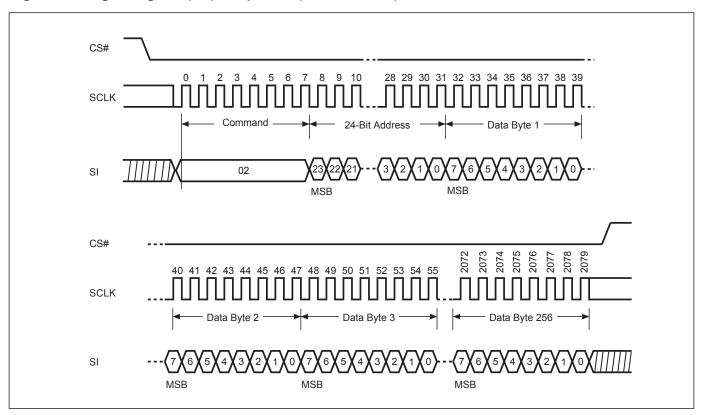
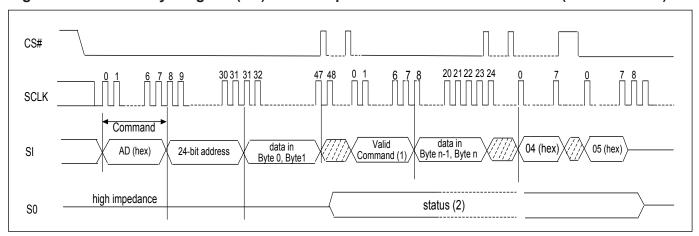




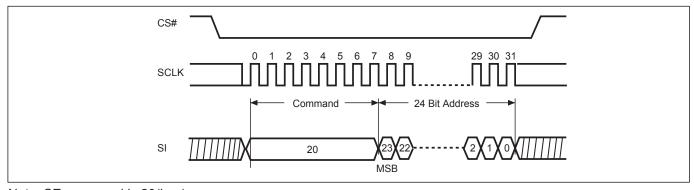
Figure 21. Continously Program (CP) Mode Sequence with Hardware Detection (Command AD)



Note: (1) During CP mode, the valid commands are CP command (AD hex), WRDI command (04 hex), RDSR command (05 hex), RDPR command (A1 hex), and RDSCUR command (2B hex).

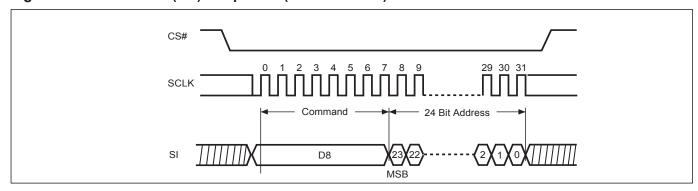
- (2) Once an internal programming operation begins, CS# goes low will drive the status on the SO pin and CS# goes high will return the SO pin to tri-state.
- (3) To end the CP mode, either reaching the highest unprotected address or sending Write Disable (WRDI) command (04 hex) may achieve it and then it is recommended to send RDSR command (05 hex) to verify if CP mode ends.

Figure 22. Sector Erase (SE) Sequence (Command 20)



Note: SE command is 20(hex).

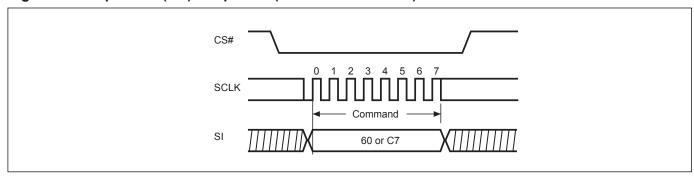
Figure 23. Block Erase (BE) Sequence (Command D8)



Note: BE command is D8(hex).



Figure 24. Chip Erase (CE) Sequence (Command 60 or C7)



Note: CE command is 60(hex) or C7(hex).

Figure 25. Deep Power-down (DP) Sequence (Command B9)

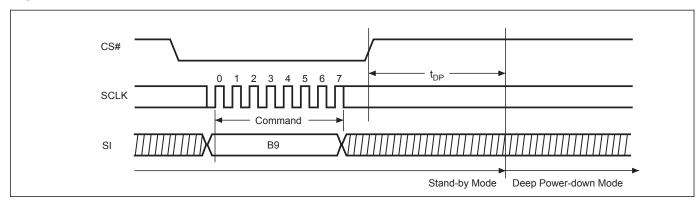


Figure 26. Release from Deep Power-down and Read Electronic Signature (RES) Sequence (Command AB)

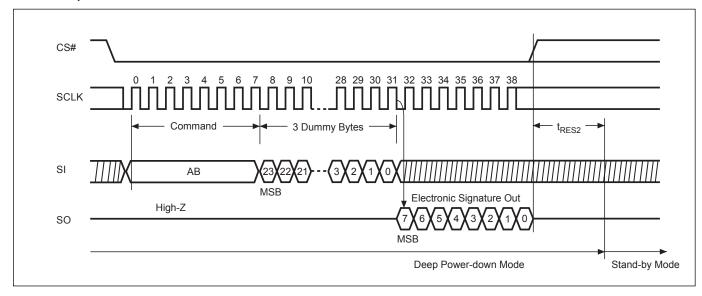




Figure 27. Release from Deep Power-down (RDP) Sequence (Command AB)

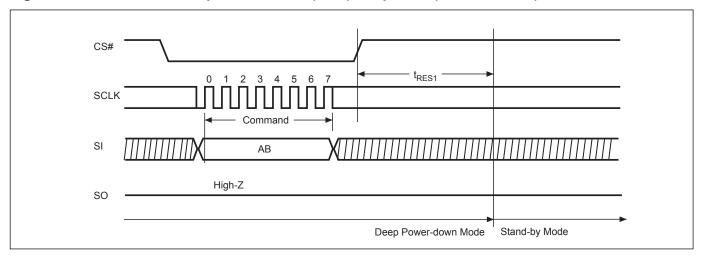
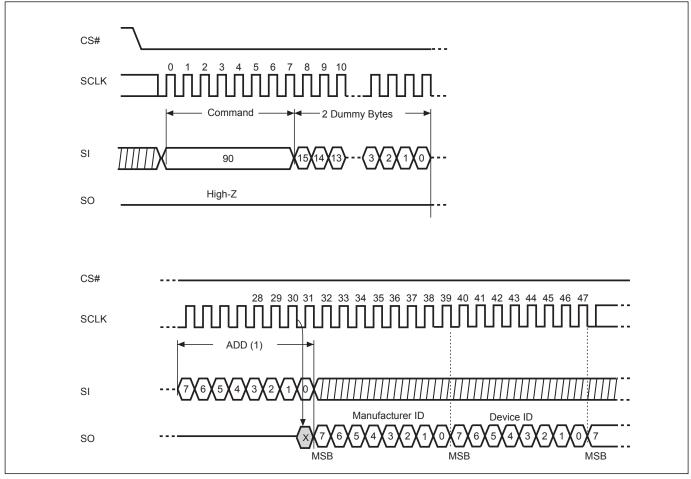


Figure 28. Read Electronic Manufacturer & Device ID (REMS) Sequence (Command 90 or EF)

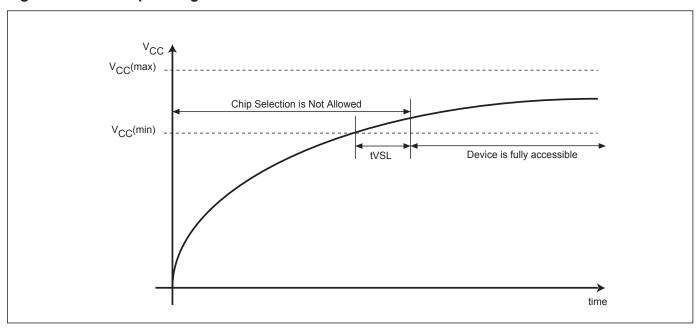


#### Notes:

- (1) ADD=00H will output the manufacturer's ID first and ADD=01H will output device ID first
- (2) Instruction is either 90(hex) or EF(hex).



Figure 29. Power-up Timing



Note: VCC (max.) is 3.6V and VCC (min.) is 2.7V.



#### RECOMMENDED OPERATING CONDITIONS

### At Device Power-Up

AC timing illustrated in Figure A is recommended for the supply voltages and the control signals at device power-up. If the timing in the figure is ignored, the device may not operate correctly.

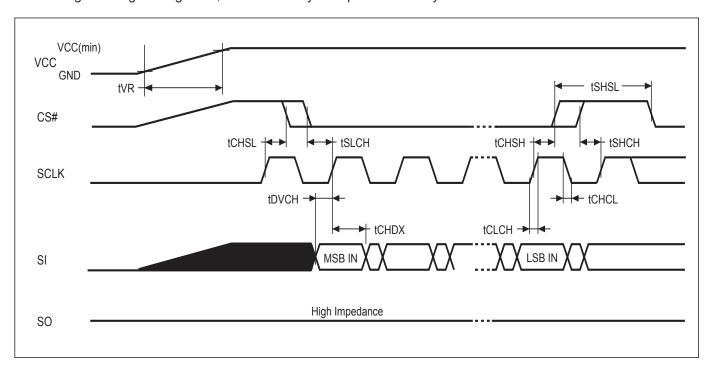


Figure A. AC Timing at Device Power-Up

Symbol	Parameter	Notes	Min.	Max.	Unit
tVR	VCC Rise Time	1	20	500000	us/V

#### Notes:

- 1. Sampled, not 100% tested.
- 2. For AC spec tCHSL, tSLCH, tDVCH, tCHDX, tSHSL, tCHSH, tSHCH, tCHCL, tCLCH in the figure, please refer to "AC CHARACTERISTICS" table.

P/N: PM1290 REV. 1.5, APR. 29, 2009



### **ERASE AND PROGRAMMING PERFORMANCE**

PARAMETER		Min.	TYP. (1)	Max. (2)	UNIT
Write Status Register Cycle Time			40	100	ms
Sector Erase Cycle Time			60	300	ms
Block Erase Cycle Time			0.7	2	s
	64Mb		50	80	s
Chip Erase Cycle Time	32Mb		25	50	s
	16Mb		14	30	s
	64Mb		30	48	s
Chip Erase Cycle Time (at ACC mode)	32Mb		15	30	s
	16Mb		8	18	s
Byte Program Time (via page program cor	nmand)		9	300	us
Page Program Cycle Time			1.4	5	ms
Page Program Cycle Time (at ACC mode)			1.4	5	ms
Erase/Program Cycle			100,000		cycles

### Note:

- 1. Typical program and erase time assumes the following conditions: 25°C, 3.3V, and checker board pattern.
- 2. Under worst conditions of 85°C and 2.7V.
- 3. System-level overhead is the time required to execute the first-bus-cycle sequence for the programming command.
- 4. Erase/Program cycles comply with JEDEC JESD-47E & A117A standard.

## **Data Retention**

PARAMETER	Condition	Min.	Max.	UNIT
Data retention	55°C	20		years

## **LATCH-UP CHARACTERISTICS**

	MIN.	MAX.							
Input Voltage with respect to GND on ACC	-1.0V	10.5V							
Input Voltage with respect to GND on all power pins, SI, CS#	-1.0V	2 VCCmax							
Input Voltage with respect to GND on SO	-1.0V	VCC + 1.0V							
Current	-100mA	+100mA							
ncludes all pins except VCC. Test conditions: VCC = 3.0V, one pin at a time.									

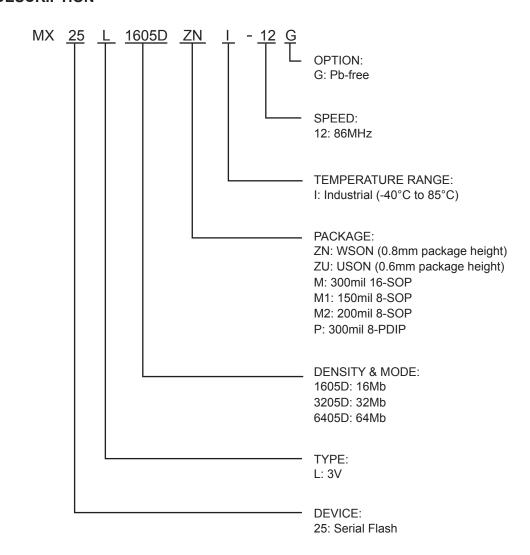


# **ORDERING INFORMATION**

PART NO.	CLOCK (MHz)	OPERATING CURRENT MAX. (mA)	STANDBY CURRENT MAX. (uA)	Temperature	PACKAGE	Remark
MX25L1605DM2I-12G	86	25	20	-40°C~85°C	8-SOP (200mil)	Pb-free
MX25L1605DMI-12G	86	25	20	-40°C~85°C	16-SOP	Pb-free
MX25L1605DM1I-12G	86	25	20	-40°C~85°C	8-SOP (150mil)	Pb-free
MX25L1605DPI-12G	86	25	20	-40°C~85°C	8-PDIP (300mil)	Pb-free
MX25L1605DZNI-12G	86	25	20	-40°C~85°C	8-WSON (6x5mm)	Pb-free
MX25L1605DZUI-12G	86	25	20	-40°C~85°C	8-USON (4x4mm)	Pb-free
MX25L3205DZNI-12G	86	25	20	-40°C~85°C	8-WSON (6x5mm)	Pb-free
MX25L3205DM2I-12G	86	25	20	-40°C~85°C	8-SOP (200mil)	Pb-free
MX25L3205DMI-12G	86	25	20	-40°C~85°C	16-SOP	Pb-free
MX25L3205DPI-12G	86	25	20	-40°C~85°C	8-PDIP (300mil)	Pb-free
MX25L3205DZUI-12G	86	25	20	-40°C~85°C	8-USON (4x4mm)	Pb-free
MX25L6405DZNI-12G	86	25	20	-40°C~85°C	8-WSON (8x6mm)	Pb-free
MX25L6405DMI-12G	86	25	20	-40°C~85°C	16-SOP	Pb-free



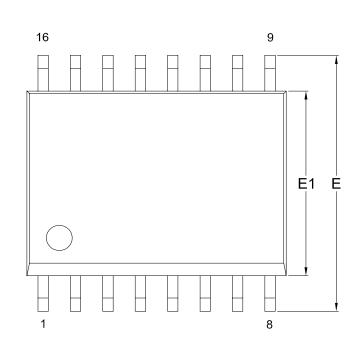
### PART NAME DESCRIPTION

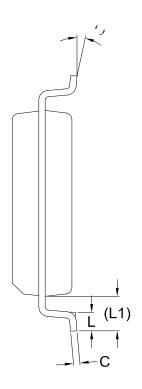


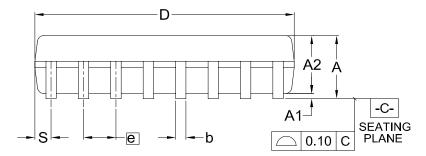


## **PACKAGE INFORMATION**

Doc. Title: Package Outline for SOP 16L (300MIL)





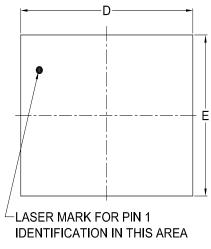


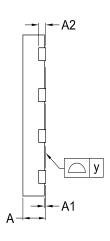
SY UNIT	MBOL	Α	A1	A2	b	С	D	E	E1	е	L	L1	s	θ
	Min.		0.10	2.34	0.36	0.20	10.10	10.10	7.42		0.40	1.31	0.51	0
mm	Nom.		0.20	2.39	0.41	0.25	10.30	10.30	7.52	1.27	0.84	1.44	0.64	5
	Max.	2.65	0.30	2.44	0.51	0.30	10.50	10.50	7.60		1.27	1.57	0.77	8
	Min.		0.004	0.092	0.014	0.008	0.397	0.397	0.292		0.016	0.052	0.020	0
Inch	Nom.		0.008	0.094	0.016	0.010	0.405	0.405	0.296	0.050	0.033	0.057	0.025	5
	Max.	0.104	0.012	0.096	0.020	0.012	0.413	0.413	0.299		0.050	0.062	0.030	8

Dwg. No.	Revision	Reference						
	Revision	JEDEC	EIAJ					
6110-1402	9	MS-013						

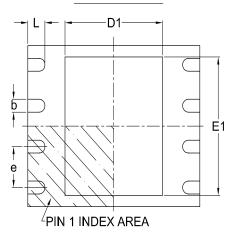


## Title: Package Outline for WSON 8L (6x5x0.8MM, LEAD PITCH 1.27MM)





**TOP VIEW** 



SIDE VIEW

# **BOTTOM VIEW**

Dimensions (inch dimensions are derived from the original mm dimensions)

\*1 : This package has exposed metal pad underneath the package, it can't contact to metal trace or pad on board.

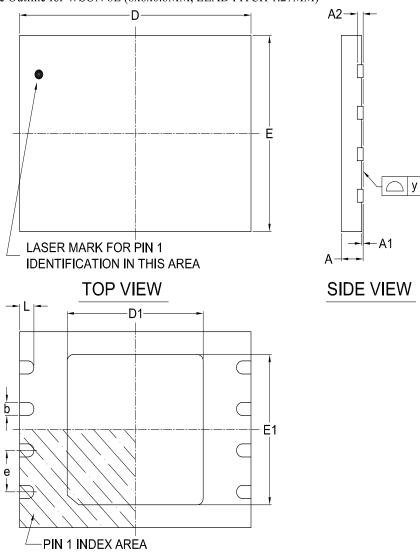
\*2 : The exposed pad size must not violate the min. metal separtion requirement, 0.2mm with terminals.

UNIT	MBOL	Α	<b>A</b> 1	A2	b	D	D1	E	E1	L	е	у
	Min.	0.70			0.35	5.90	3.30	4.90	3.90	0.50	_	0.00
mm	Nom.			0.20	0.40	6.00	3.40	5.00	4.00	0.60	1.27	_
	Max.	0.80	0.05	-	0.48	6.10	3.50	5.10	4.10	0.75	1	0.08
	Min.	0.028		-	0.014	0.232	0.129	0.193	0.154	0.020	1	0.00
Inch	Nom.	1	1	0.008	0.016	0.236	0.134	0.197	0.157	0.024	0.05	_
	Max.	0.032	0.002	-	0.019	0.240	0.138	0.201	0.161	0.030	_	0.003

DWC NO	REVISION		ICCUE DATE		
DWG.NO.		JEDEC	EIAJ		ISSUE DATE
6110-3401	4	MO-220			2007/09/20



Doc. Title: Package Outline for WSON 8L (8x6x0.8MM, LEAD PITCH 1.27MM)



Dimensions (inch dimensions are derived from the original mm dimensions)

**BOTTOM VIEW** 

\*1 : This package has exposed metal pad underneath the package, it can't contact to metal trace or pad on board.

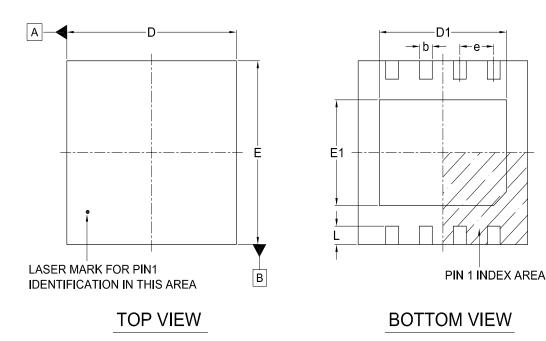
\*2 : The exposed pad size must not violate the min. metal separtion requirement, 0.2mm with terminals.

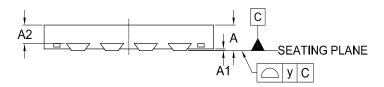
UNIT	MBOL	Α	<b>A</b> 1	A2	b	D	D1	E	E1	L	е	у
	Min.	0.70		_	0.35	7.90	4.65	5.90	4.55	0.40		0.00
mm	Nom.	-		0.20	0.40	8.00	4.70	6.00	4.60	0.50	1.27	_
	Max.	0.80	0.05		0.48	8.10	4.75	6.10	4.65	0.60	1	80.0
	Min.	0.028		_	0.014	0.311	0.183	0.232	0.179	0.016	1	0.00
Inch	Nom.			0.008	0.016	0.315	0.185	0.236	0.181	0.020	0.05	
	Max.	0.032	0.002	_	0.019	0.319	0.187	0.240	0.183	0.024	-	0.003

Dwg. No.	Revision	Reference							
		JEDEC	EIAJ						
6110-3402	5	MO-220							



## Title: Package Outline for USON 8L (4x4x0.6MM, LEAD PITCH 0.8MM)





# SIDE VIEW

Dimensions (inch dimensions are derived from the original mm dimensions)

- \*1 : This package has exposed metal pad underneath the package, it can't contact to metal trace or pad on board.
- \*2 : The exposed pad size must not violate the min. metal separtion requirement, 0.2mm with terminals.

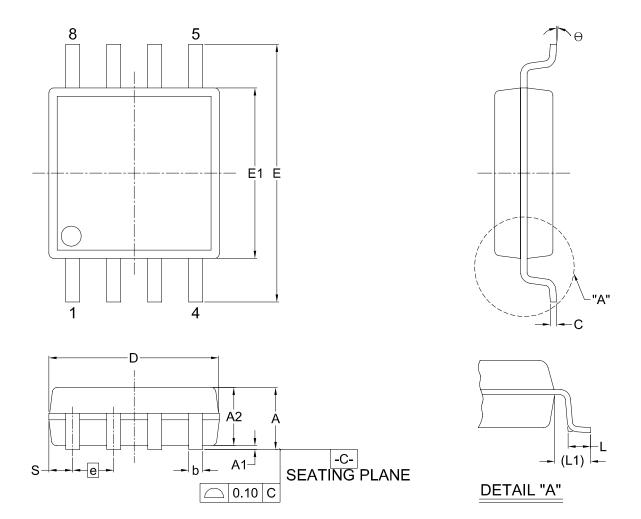
UNIT	MBOL	Α	A1	A2	b	D	D1	E	E1	L	e	у
	Min.	0.50		_	0.25	3.90	2.90	3.90	2.20	0.35	_	0.00
mm	Nom.	0.55	0.04	0.40	0.30	4.00	3.00	4.00	2.30	0.40	0.80	_
	Max.	0.60	0.05	0.43	0.35	4.10	3.10	4.10	2.40	0.45	_	0.08
	Min.	0.020		1	0.010	0.154	0.114	0.154	0.087	0.014	1	0.00
Inch	Nom.	0.022	0.002	0.016	0.011	0.157	0.118	0.157	0.091	0.016	0.031	
	Max.	0.024	0.002	0.017	0.014	0.161	0.122	0.161	0.094	0.018		0.003

ĺ	DWG.NO.	REVISION		REFERENCE	ISSUE DATE
	DWG.NO.	REVISION	JEDEC	EIAJ	ISSUE DATE
	6110-3601	3	MO-252		2008/03/12

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Doc. Title: Package Outline for SOP 8L 200MIL (official name - 209MIL)

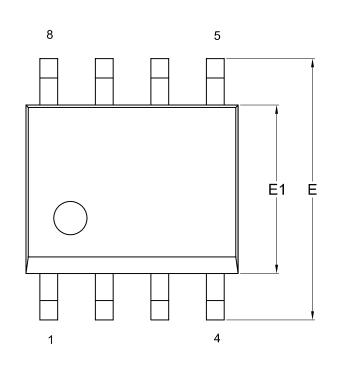


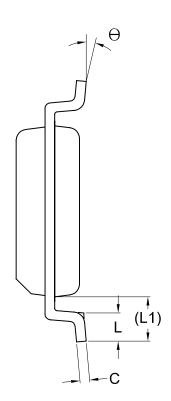
SY	MBOL		A1	A2	b	C	D	Е	E1	•		1.4	c	
UNIT		Α	AI	AZ	b	C	D			е	L	L1	S	θ
	Min.		0.05	1.70	0.36	0.19	5.13	7.70	5.18		0.50	1.21	0.62	0
mm	Nom.		0.15	1.80	0.41	0.20	5.23	7.90	5.28	1.27	0.65	1.31	0.74	5
	Max.	2.16	0.20	1.91	0.51	0.25	5.33	8.10	5.38		0.80	1.41	0.88	8
	Min.		0.002	0.067	0.014	0.007	0.202	0.303	0.204		0.020	0.048	0.024	0
Inch	Nom.		0.006	0.071	0.016	0.008	0.206	0.311	0.208	0.050	0.026	0.052	0.029	5
	Max.	0.085	0.008	0.075	0.020	0.010	0.210	0.319	0.212		0.031	0.056	0.035	8

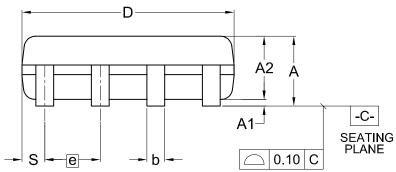
Davis No	Revision	Reference					
Dwg. No.		JEDEC	EIAJ				
6110-1406	2						



Title: Package Outline for SOP 8L (150MIL)





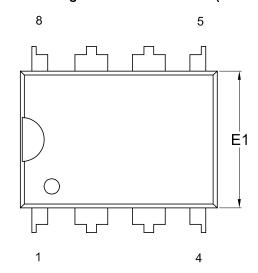


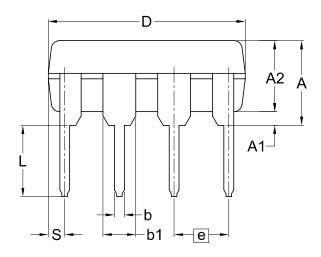
SY	MBOL	^	A1	A2	4	C	D	Е	E1			1.4	S	)
UNIT		Α	AI	AZ	b	ر	ט			е		L1	3	Φ
	Min.		0.10	1.35	0.36	0.15	4.77	5.80	3.80		0.46	0.85	0.41	0
mm	Nom.		0.15	1.45	0.41	0.20	4.90	5.99	3.90	1.27	0.66	1.05	0.54	5
	Max.	1.75	0.20	1.55	0.51	0.25	5.03	6.20	4.00		0.86	1.25	0.67	8
	Min.	_	0.004	0.053	0.014	0.006	0.188	0.228	0.150		0.018	0.033	0.016	0
Inch	Nom.		0.006	0.057	0.016	0.008	0.193	0.236	0.154	0.050	0.026	0.041	0.021	5
	Max.	0.069	0.008	0.061	0.020	0.010	0.198	0.244	0.158		0.034	0.049	0.026	8

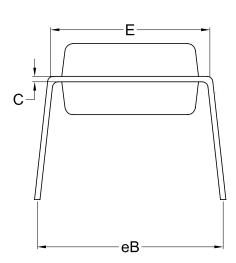
DWC NO	REVISION		ISSUE DATE		
DWG.NO.	REVISION	JEDEC EIAJ			1990E DATE
6110-1401	6	MS-012			11-26-'03



# Title: Package Outline for PDIP 8L (300MIL)







SY UNIT	MBOL	Α	<b>A</b> 1	A2	b	b1	С	D	E	E1	е	eВ	L	s
	Min.	_	0.38	3.18	0.36	1.14	0.20	9.02	7.62	6.22		7.87	2.92	0.76
mm	Nom.		_	3.30	0.46	1.52	0.25	9.27	7.87	6.35	2.54	8.89	3.30	1.14
	Max.	5.33	_	3.43	0.56	1.78	0.36	10.16	8.13	6.48	-	9.53	3.81	1.52
	Min.		0.015	0.125	0.014	0.045	0.008	0.355	0.300	0.245		0.310	0.115	0.030
Inch	Nom.		_	0.130	0.018	0.060	0.010	0.365	0.310	0.250	0.100	0.350	0.130	0.045
	Max.	0.210	_	0.135	0.022	0.070	0.014	0.400	0.320	0.255		0.375	0.150	0.060

DWC NO	REVISION		REFERENCE	ICCUE DATE	
DWG.NO.	REVISION	JEDEC	EIAJ	ISSUE DATE	
6110-0201	6	MS-001		09-01-'06	



MX25L1605D MX25L3205D MX25L6405D

## **REVISION HISTORY**

Revision No.	•	Page	Date
1.0	Removed "Preliminary"	P1	MAR/07/2008
1.1	1. Dual I/O Pre-released	P1,3,21,31	MAY/12/2008
1.2	Added 8-land USON package information	P2,4,46, 47,50	JUL/08/2008
1.3	1. Modified figure 4 & 5 waveform	P28	AUG/15/2008
	2. Revised VHH spec from 11.0V(typ.)~11.5V(max.) to 9.5V(min.)~10.5V(max.)	P4,8,30,45	
1.4	1. Revised sector erase time spec from 90ms(typ.) to 60ms(typ.)	P32,45	OCT/01/2008
	2. Removed "Advanced Information" for MX25L3205DZUI-12G	P46	
1.5	1. Deleted Low Vcc function	P1,6,27	APR/29/2009
		33,43	
	2. Added condition of data retention 20 years	P1,45	
	3. Changed typ. tSHSL spec from 100ns to 40ns	P31	
	4. Changed AC CHARACTERISTICS: Min. tCH and tCL into 5.5/5.5	P31	
	when fc=86MHz and 13/13 when fR=33MHz		
	5. Revised copyright page	P56	



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